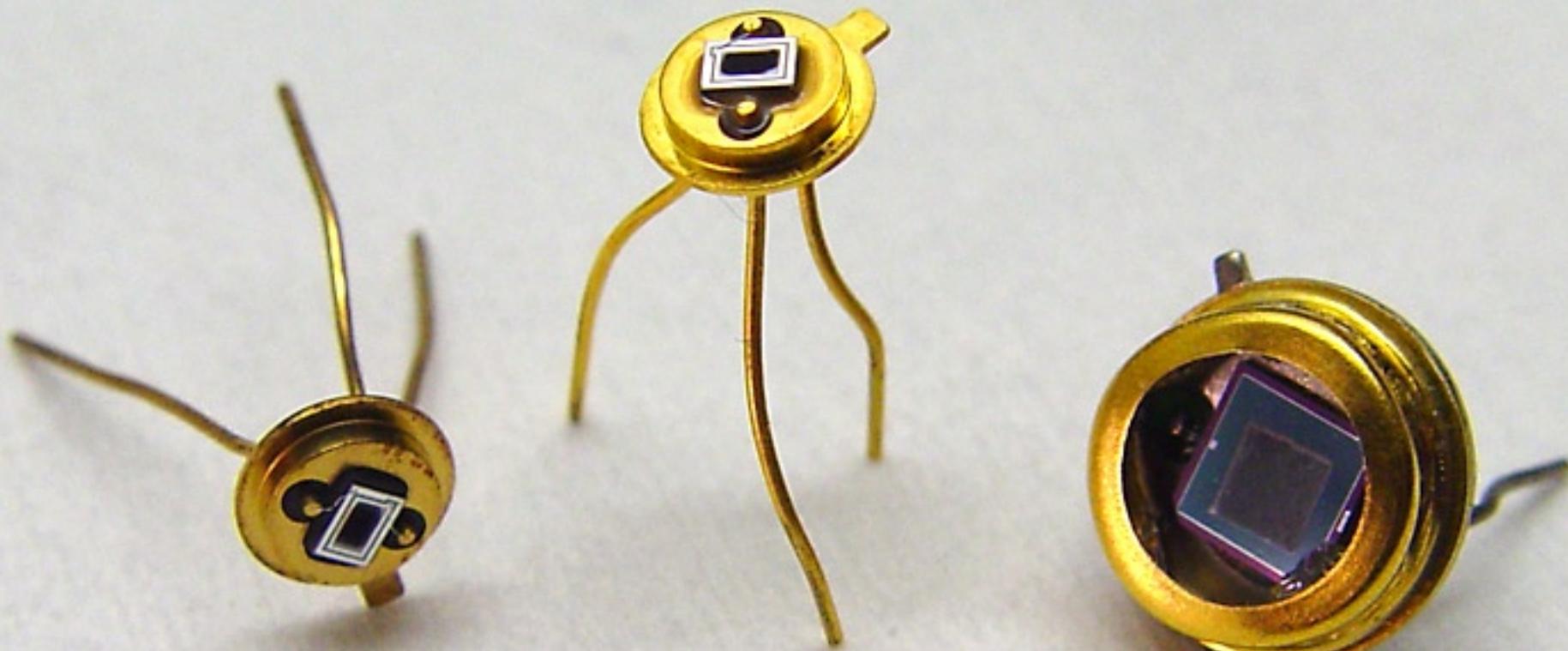
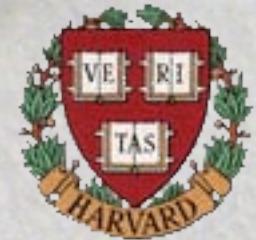


Femtosecond laser-assisted microstructuring of silicon for novel detector, sensing and display technologies



2003 LEOS Annual Meeting
Tucson, AZ, 29 October 2003





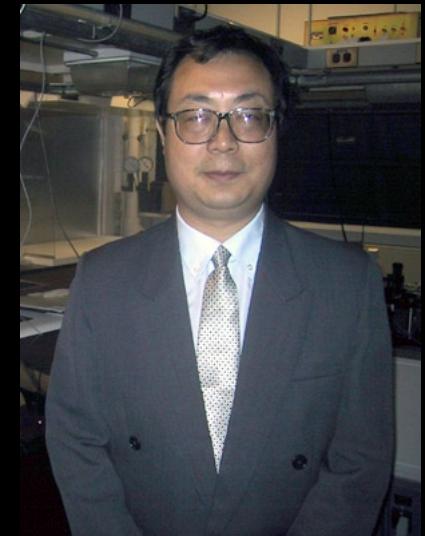
Eric Mazur



Jim Carey



Catherine Crouch



Mengyan Shen

and also....

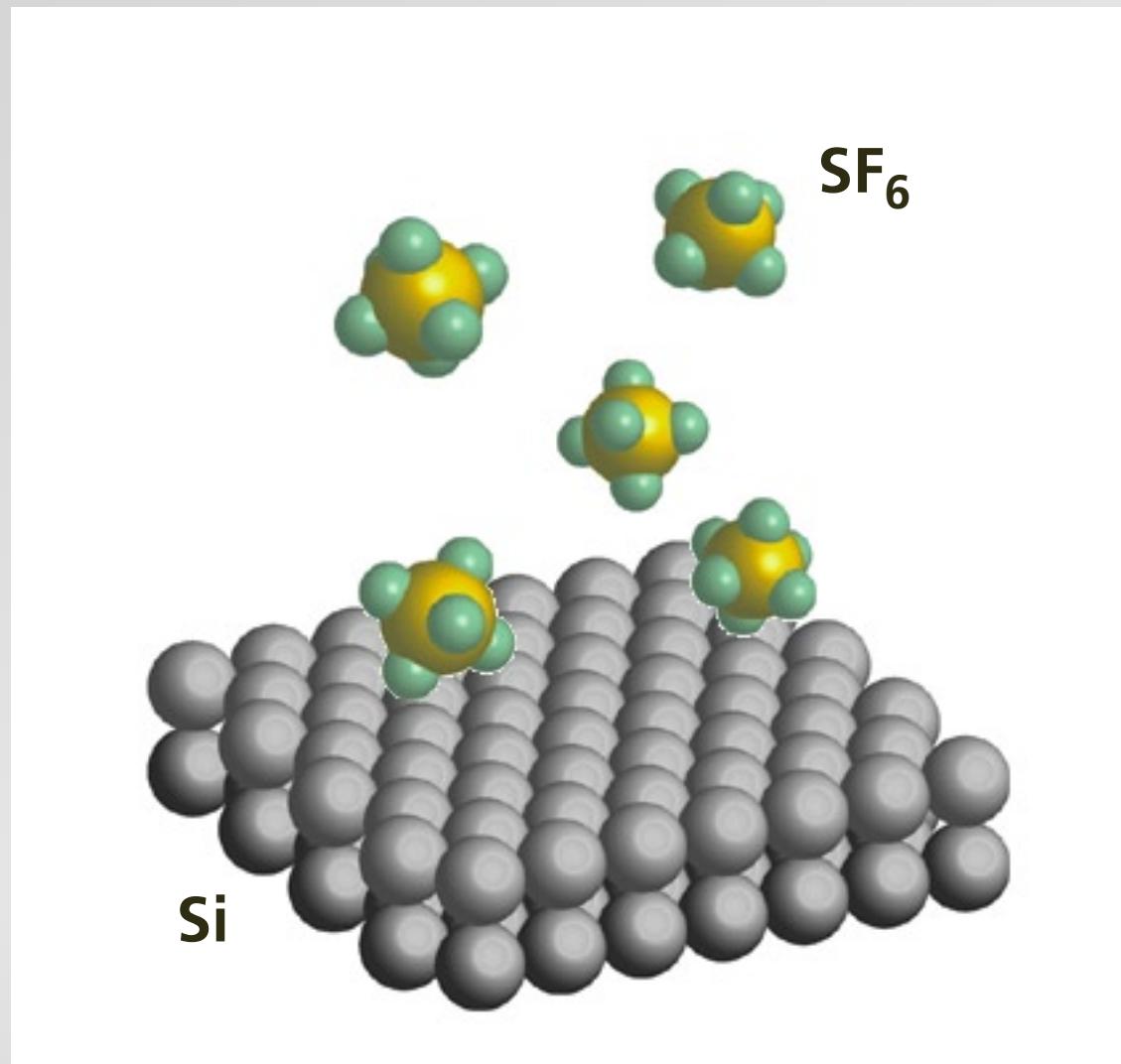
**Tsing-Hua Her
Shrenik Deliwala
Richard Finlay
Michael Sheehy
Brian Tull
Jeffrey Warrander
Claudia Wu
Rebecca Younkin**

**Dr. John Chervinsky
Dr. Joshua Levinson**

**Dr. François Génin (LLNL)
Dr. Richard Farrell
Dr. Arieh Karger (RMD)
Dr. Richard Meyers (RMD)**

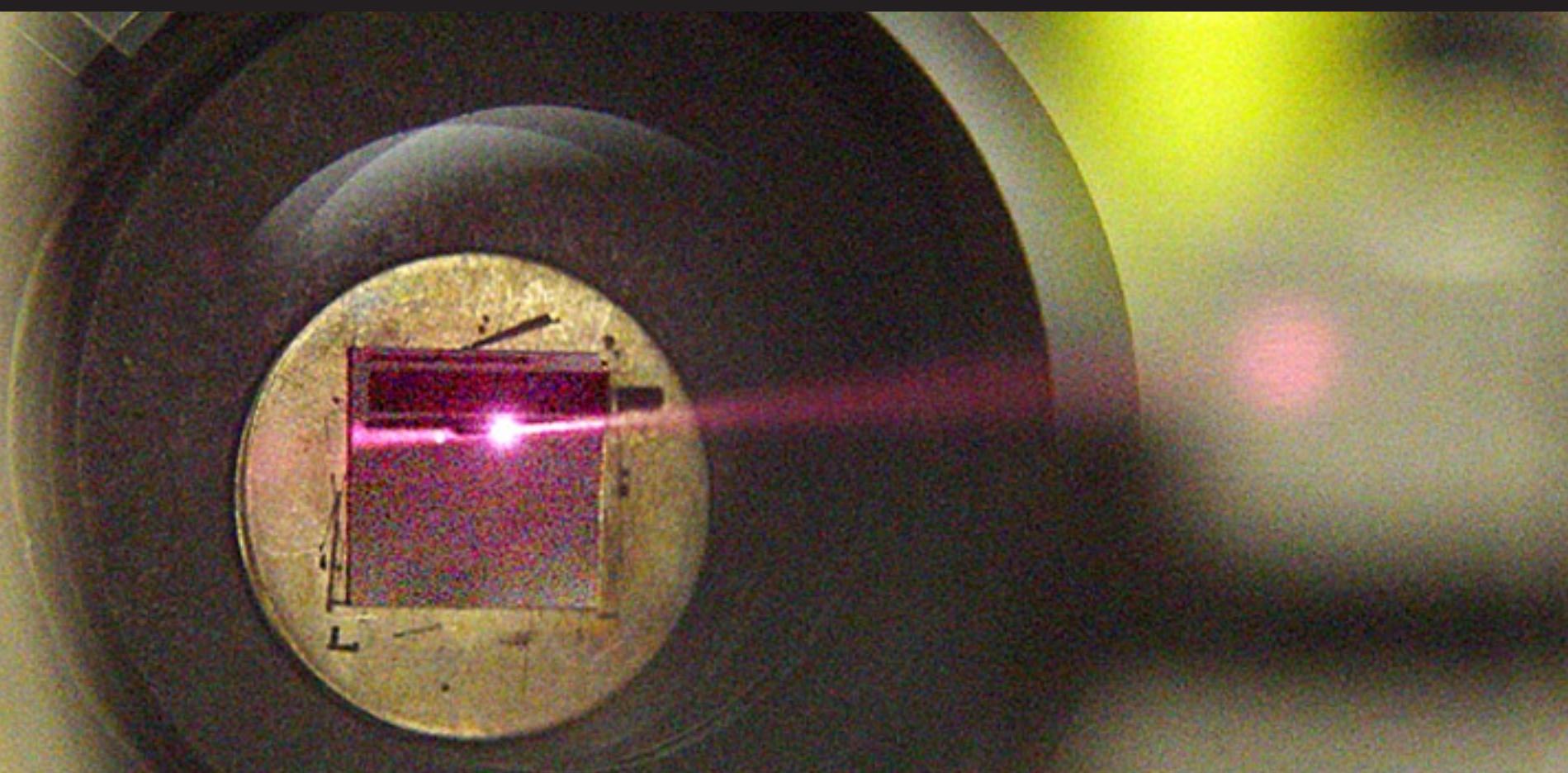
**Prof. Michael Aziz
Prof. Cynthia Friend
Prof. Li Zhao (Fudan)**

Introduction

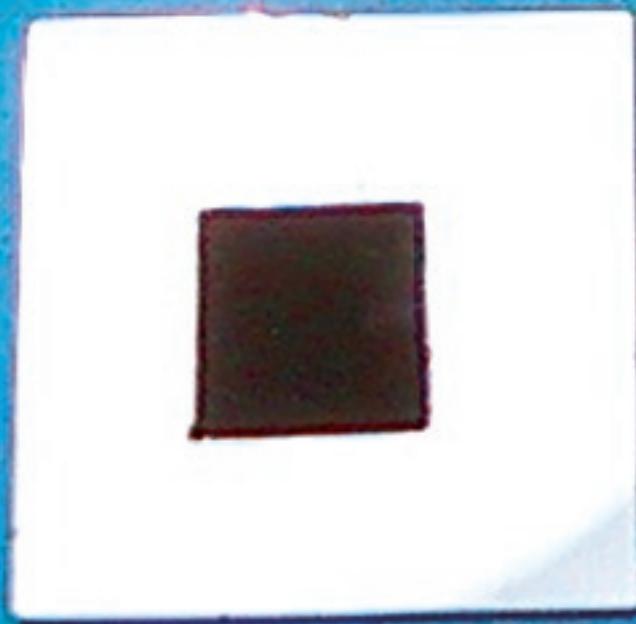


irradiate with 100-fs 10 kJ/m² pulses

Introduction



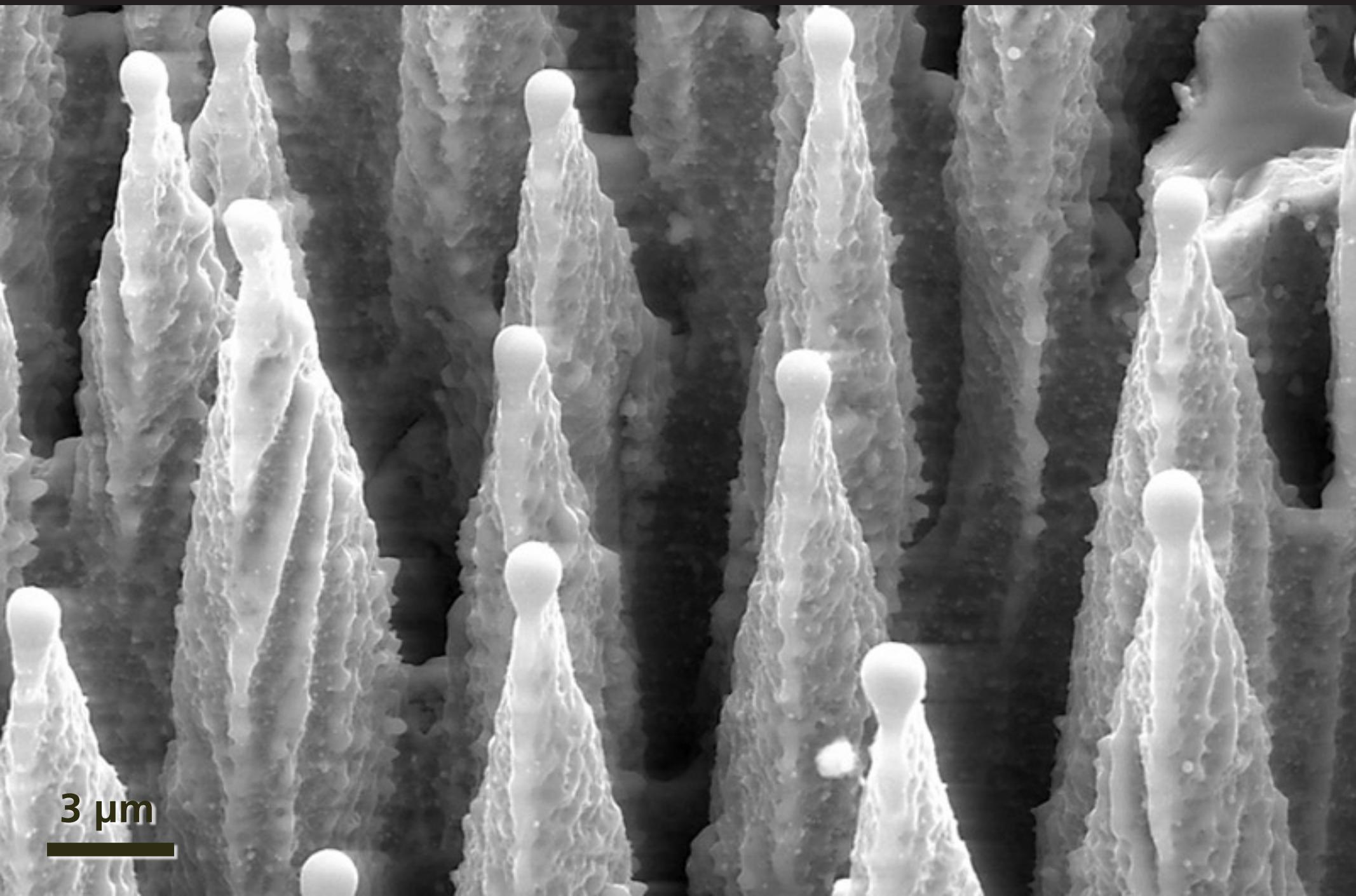
Introduction



“black silicon”

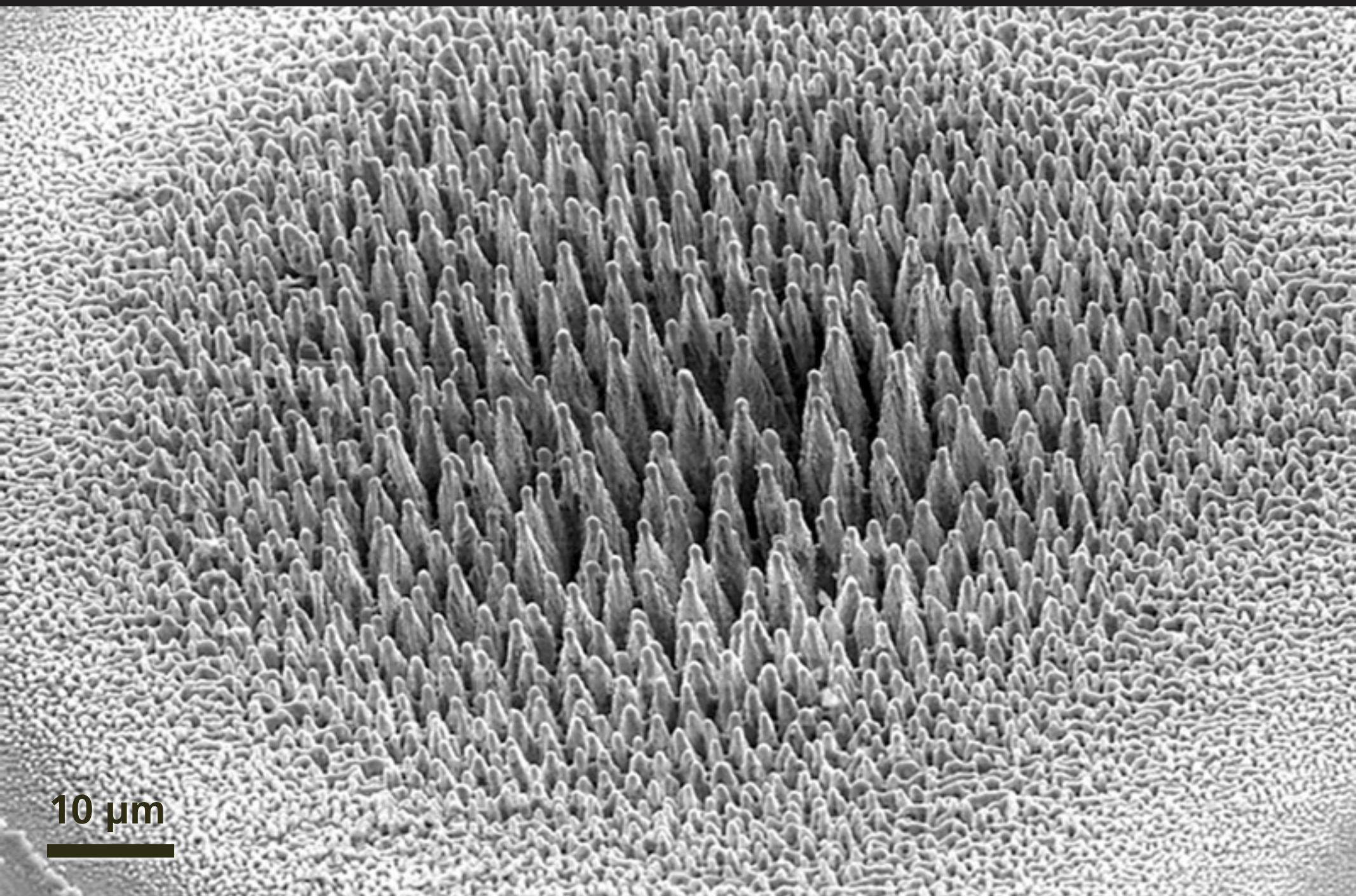


Introduction

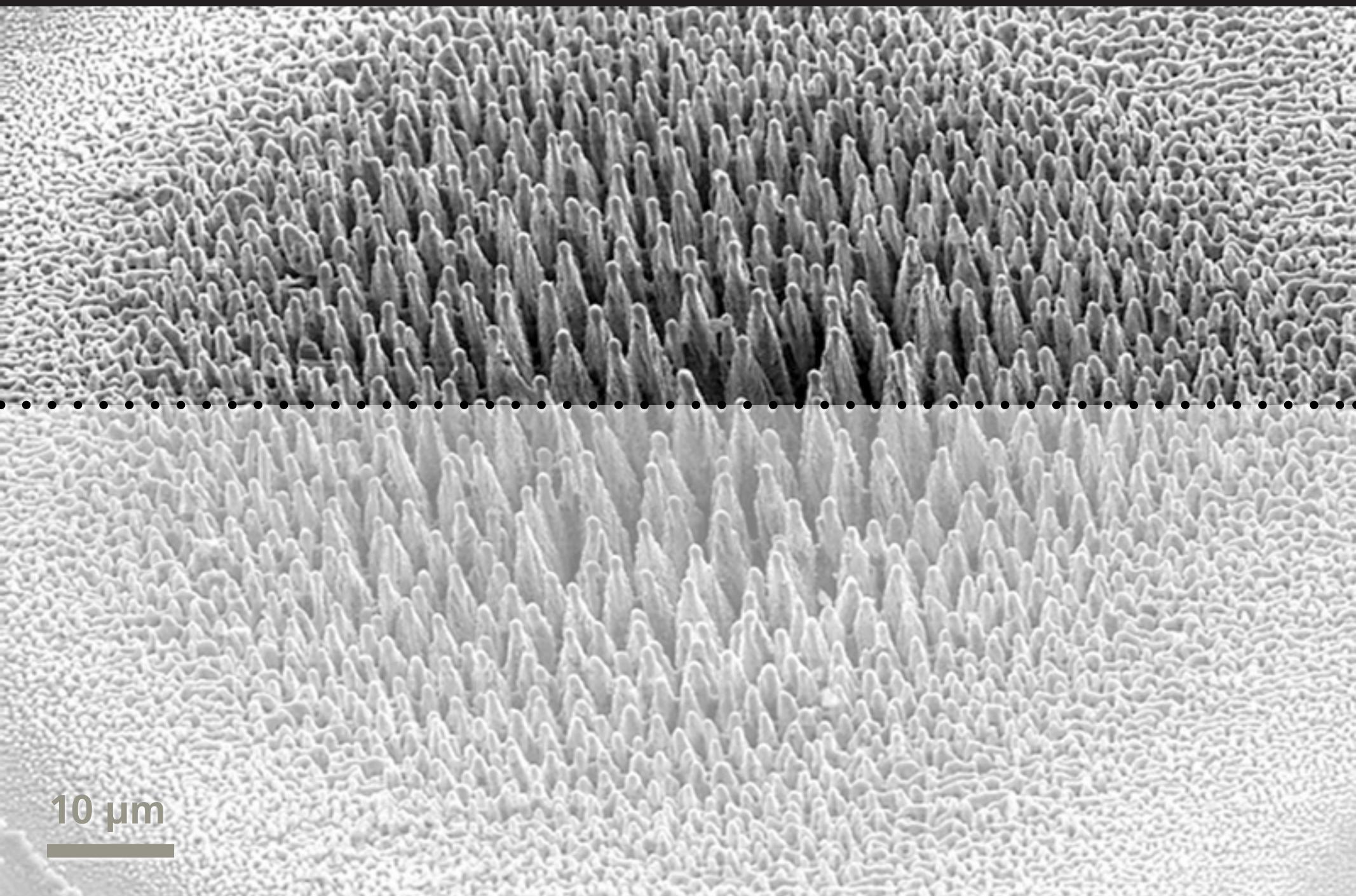


3 μm

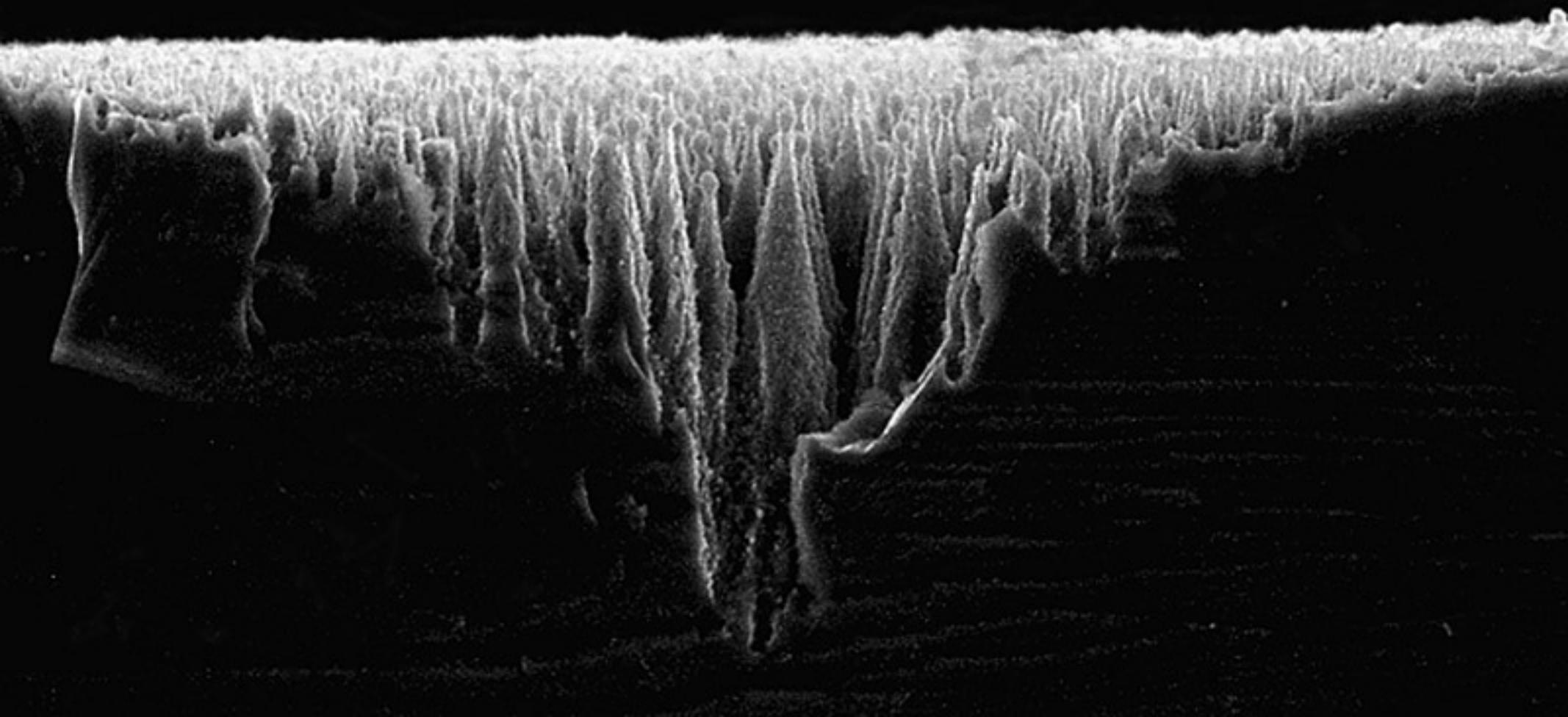
Introduction



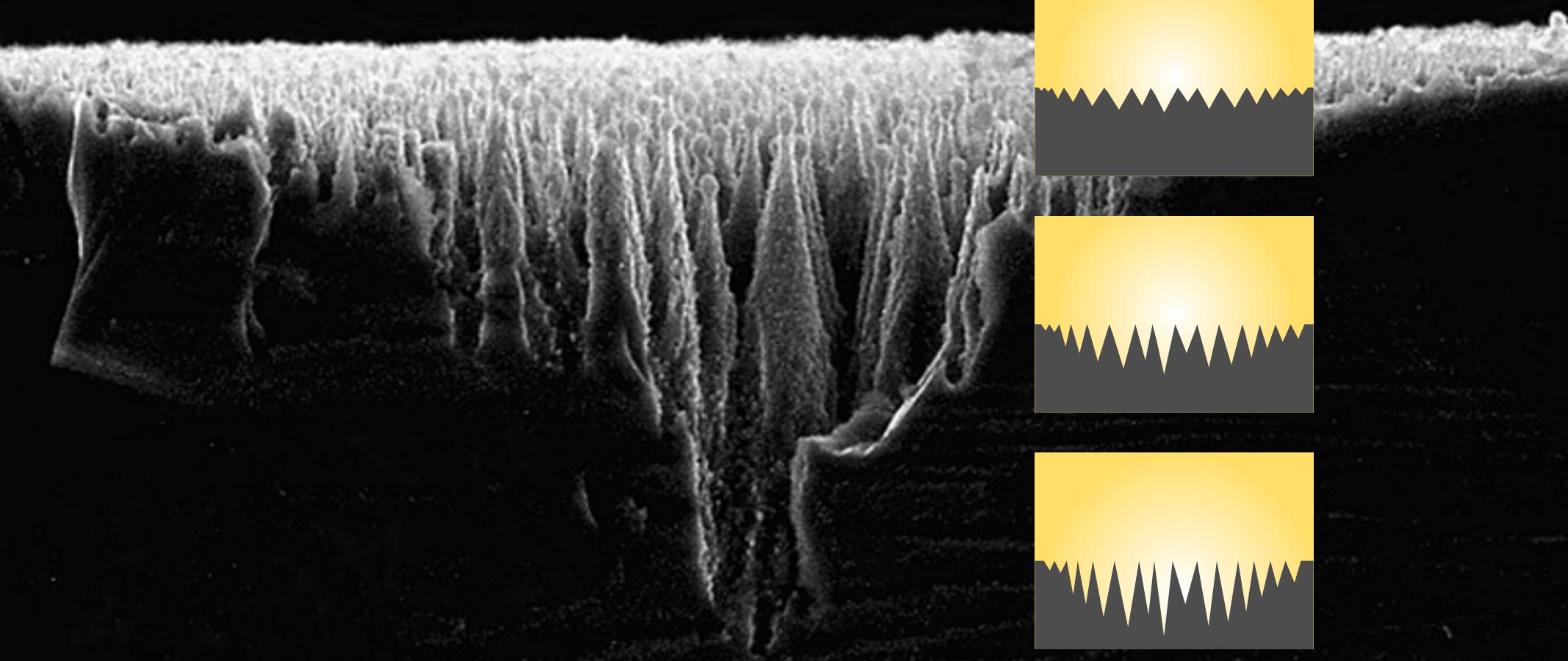
Introduction



Introduction



Introduction



Introduction

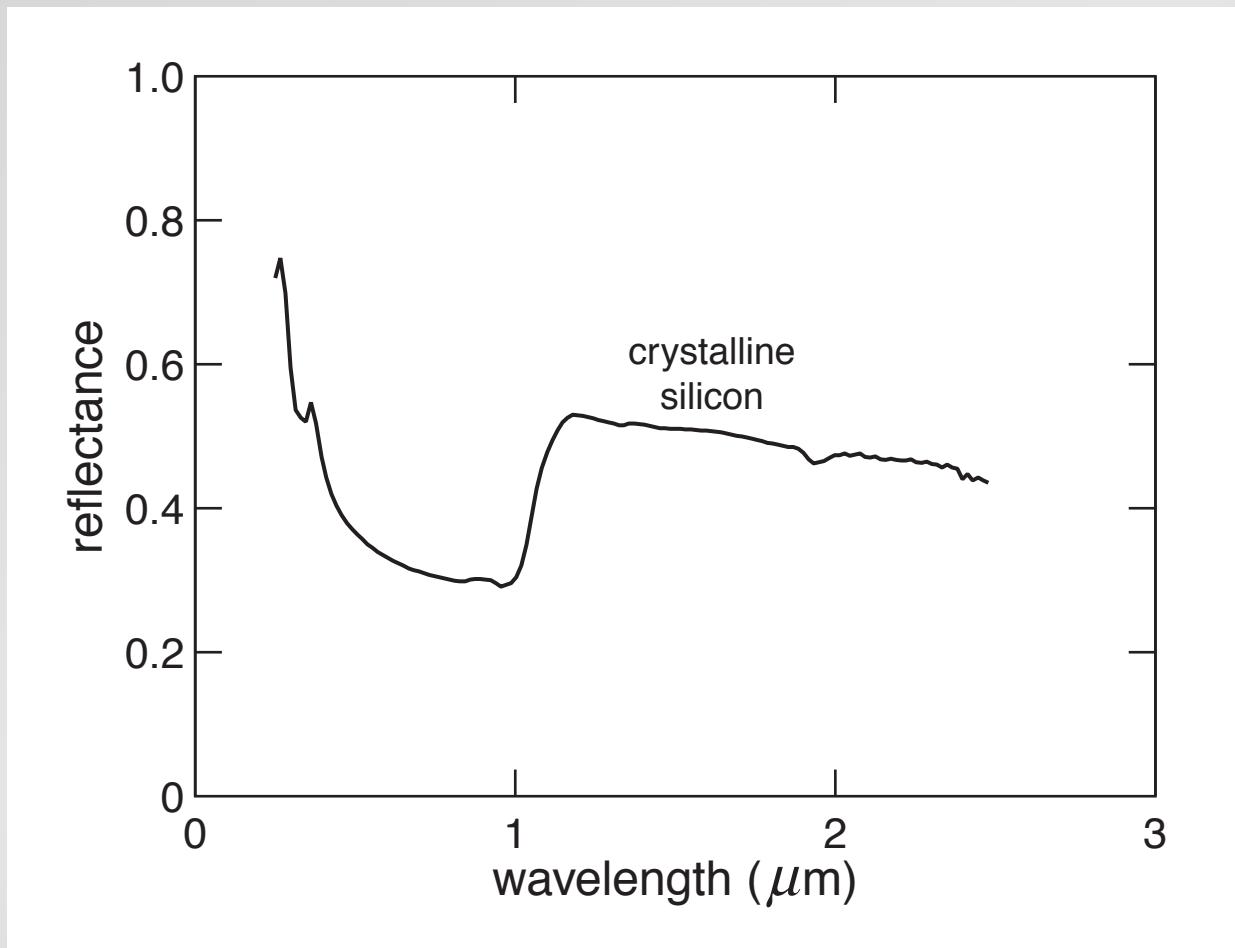
- maskless etching process
- self-organized, tall microstructures
- highly light absorbing

Outline

- properties
- structural and chemical analysis
- detectors
- outlook

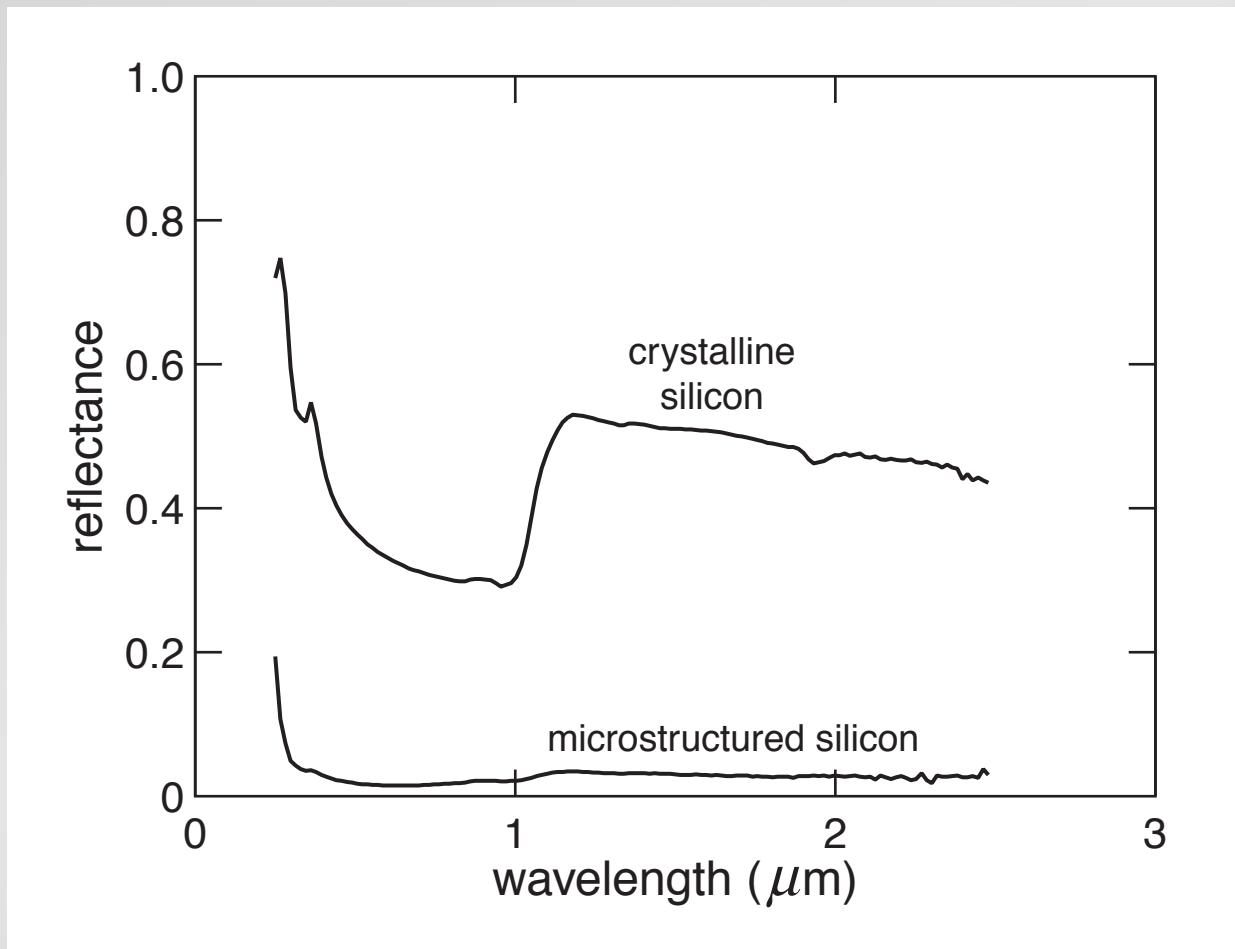
Properties

reflectance (integrating sphere)



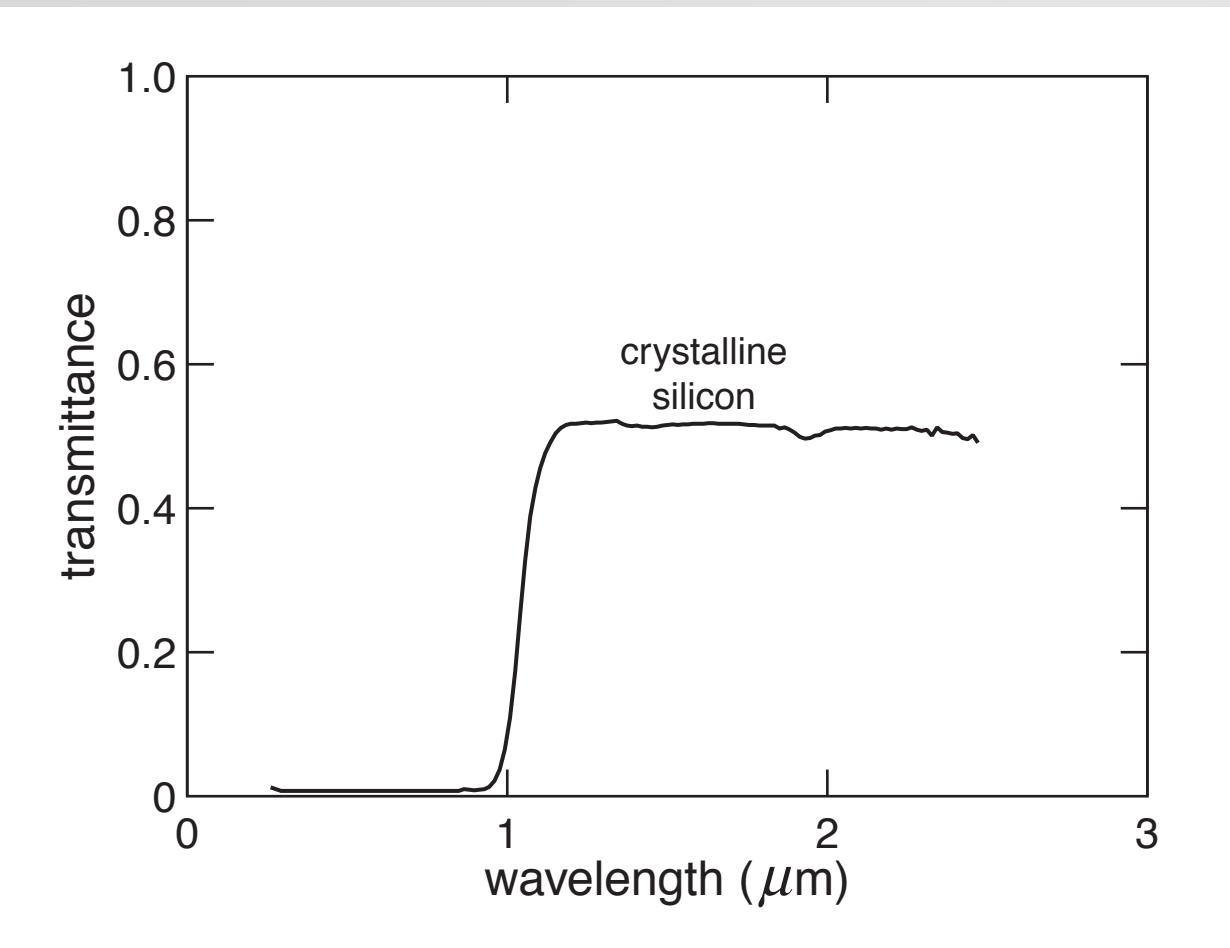
Properties

reflectance (integrating sphere)



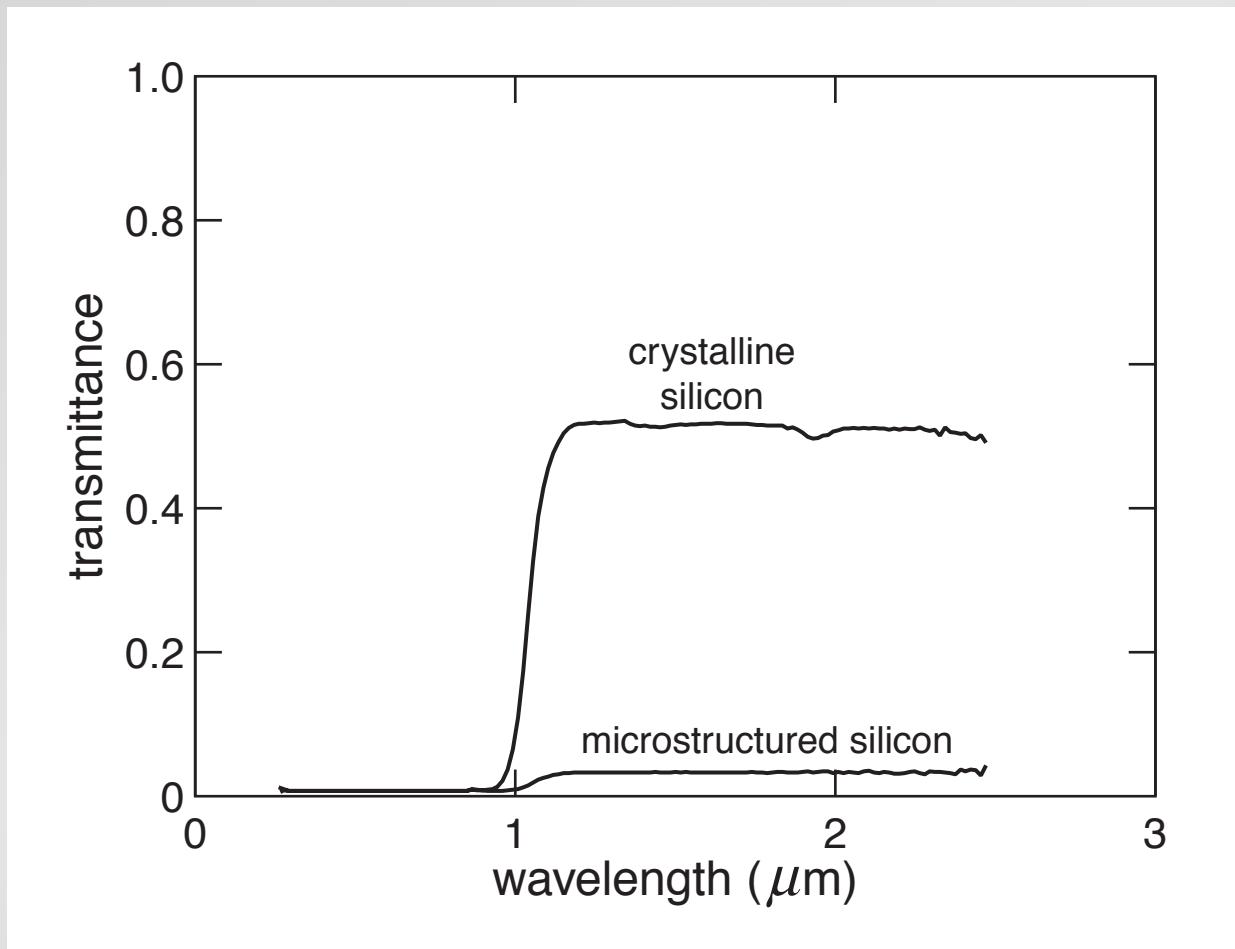
Properties

transmittance (integrating sphere)



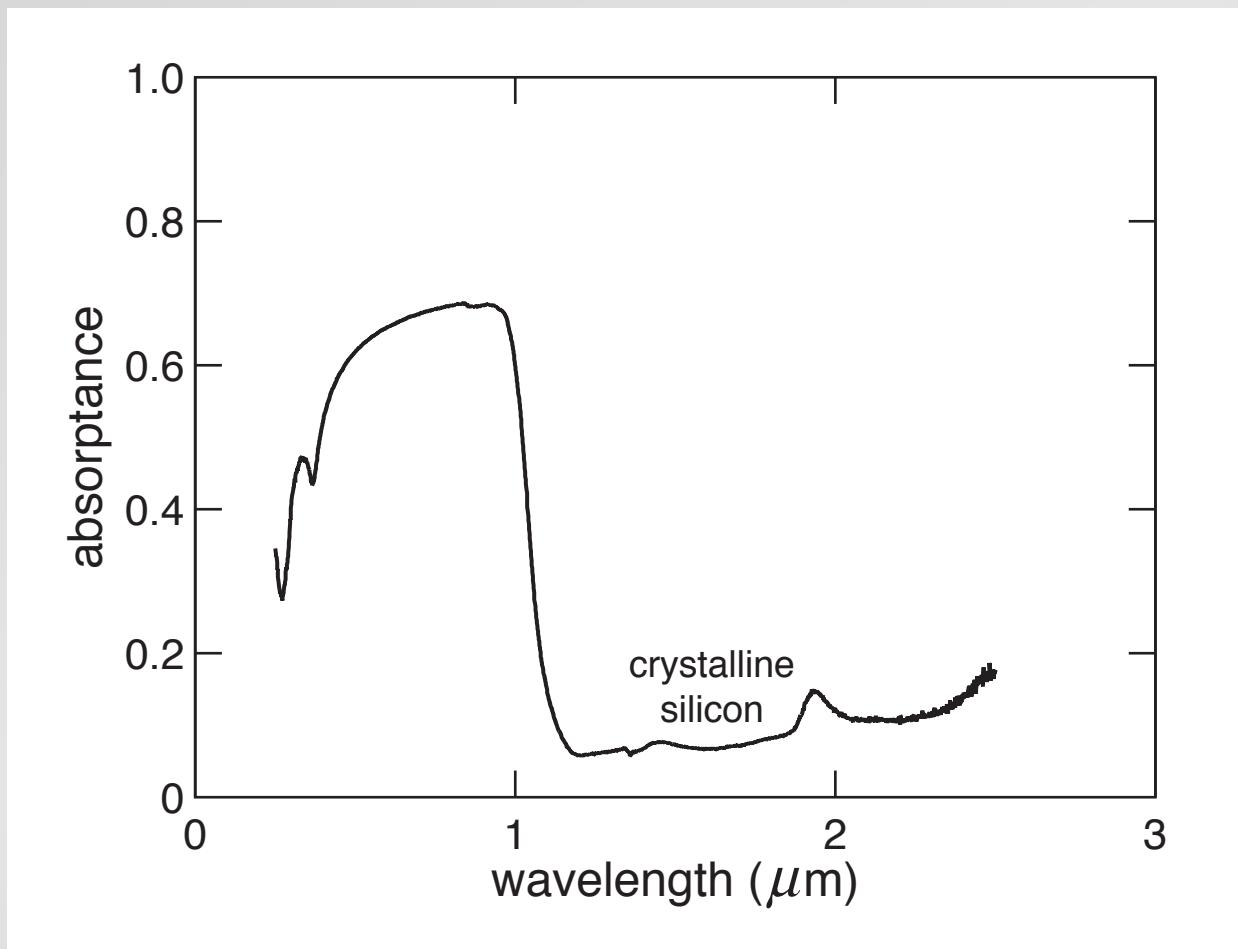
Properties

transmittance (integrating sphere)



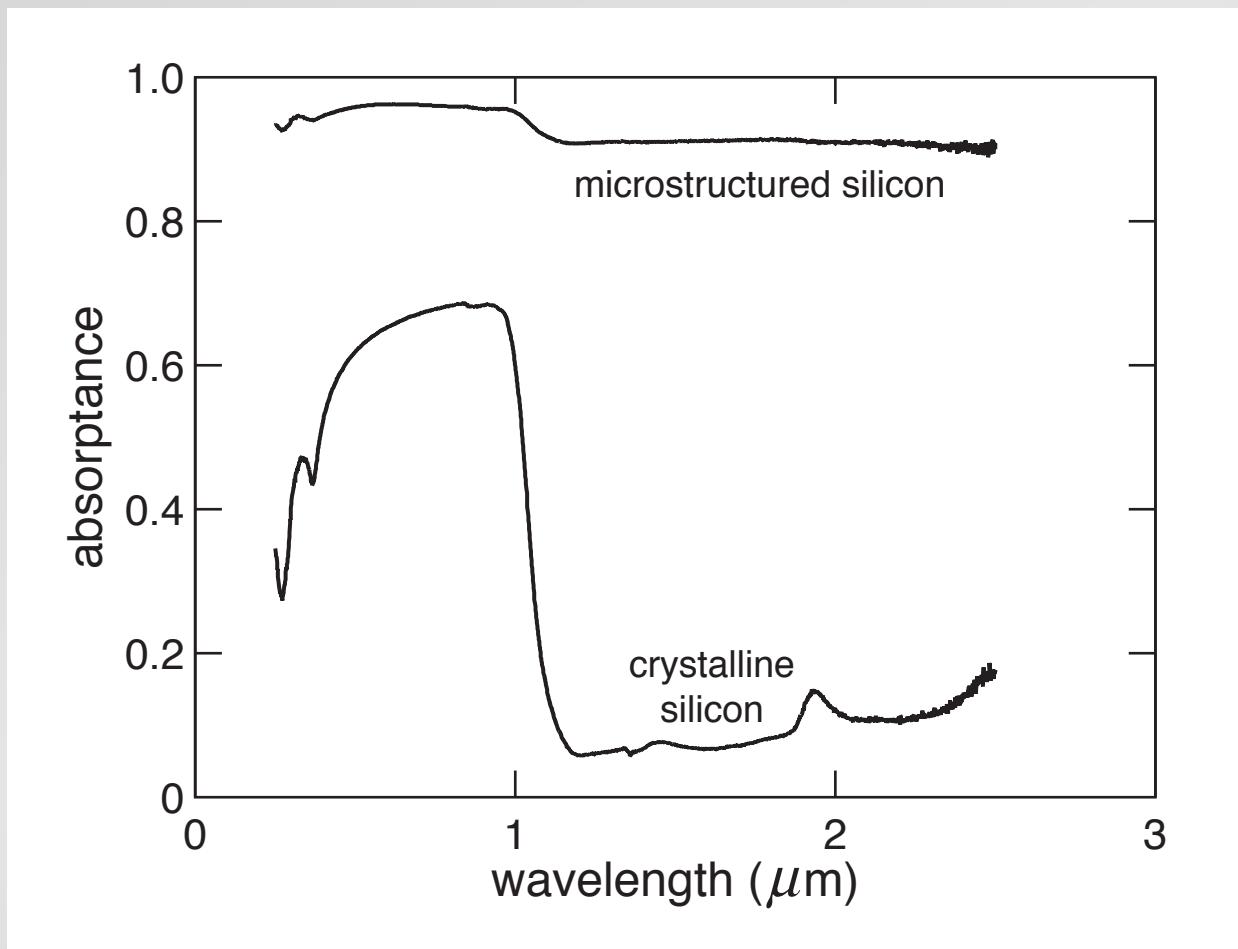
Properties

absorptance ($1 - R - T$)



Properties

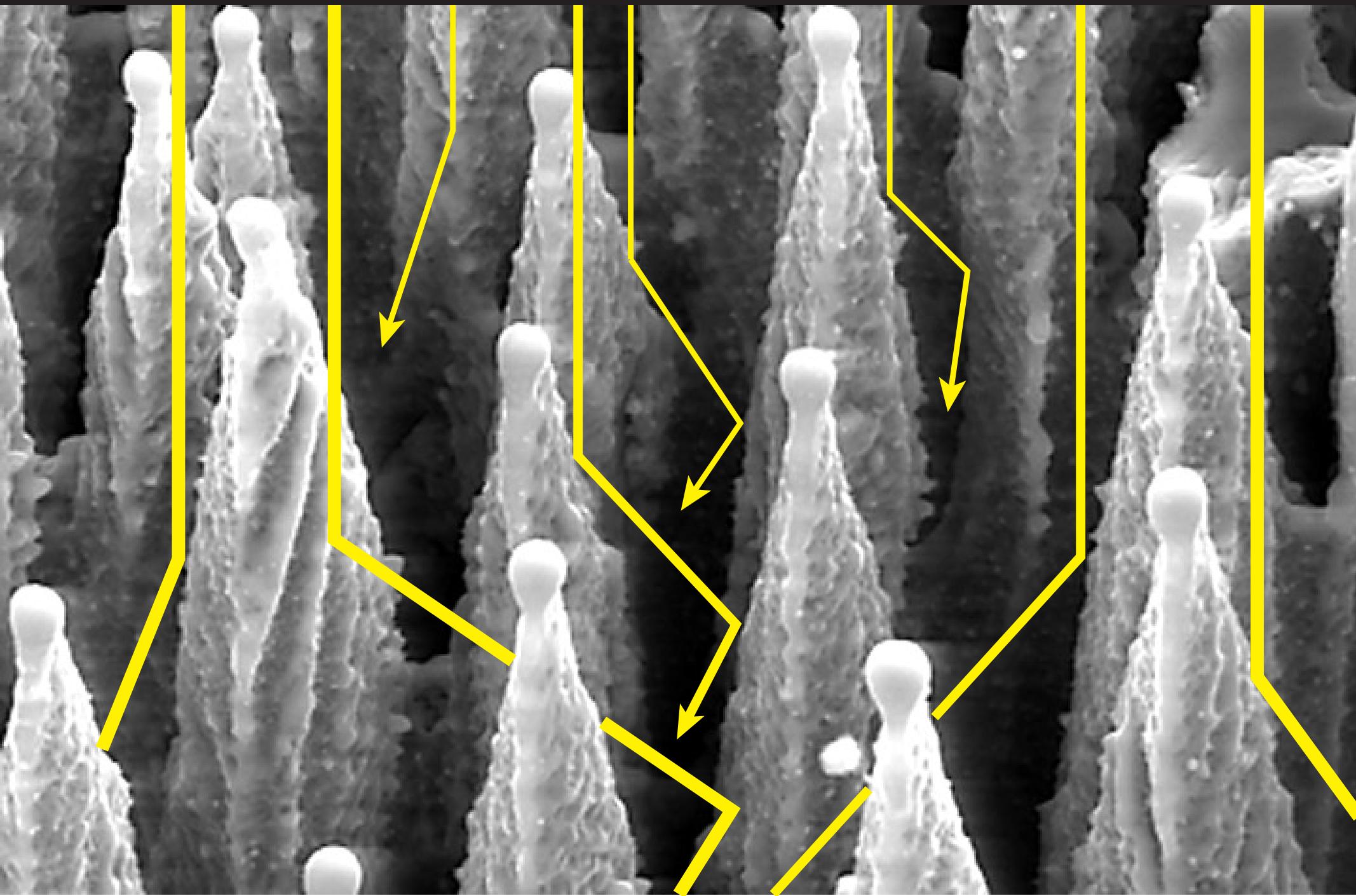
absorptance ($1 - R - T$)



Properties

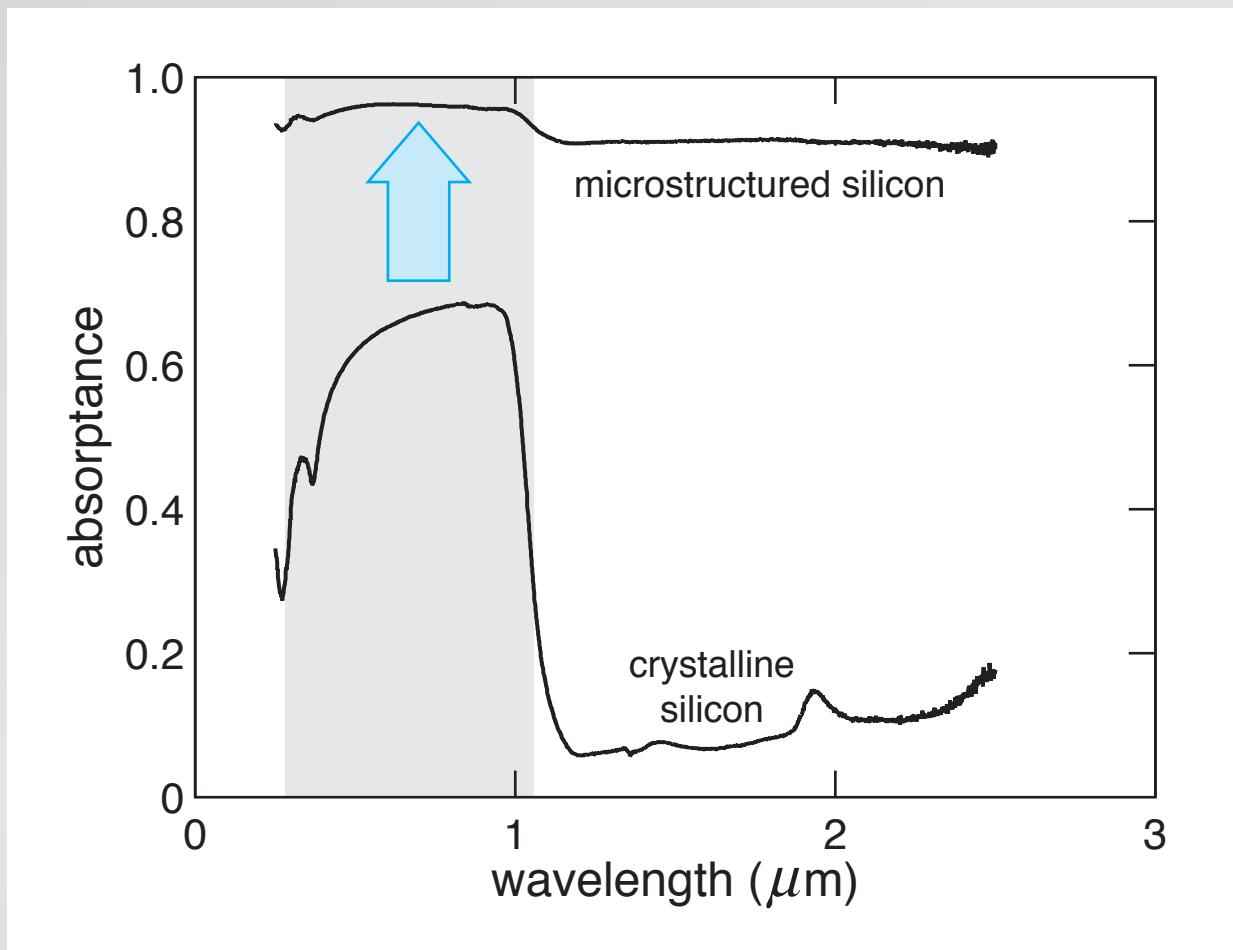
What causes the near-unity absorptance?

Properties



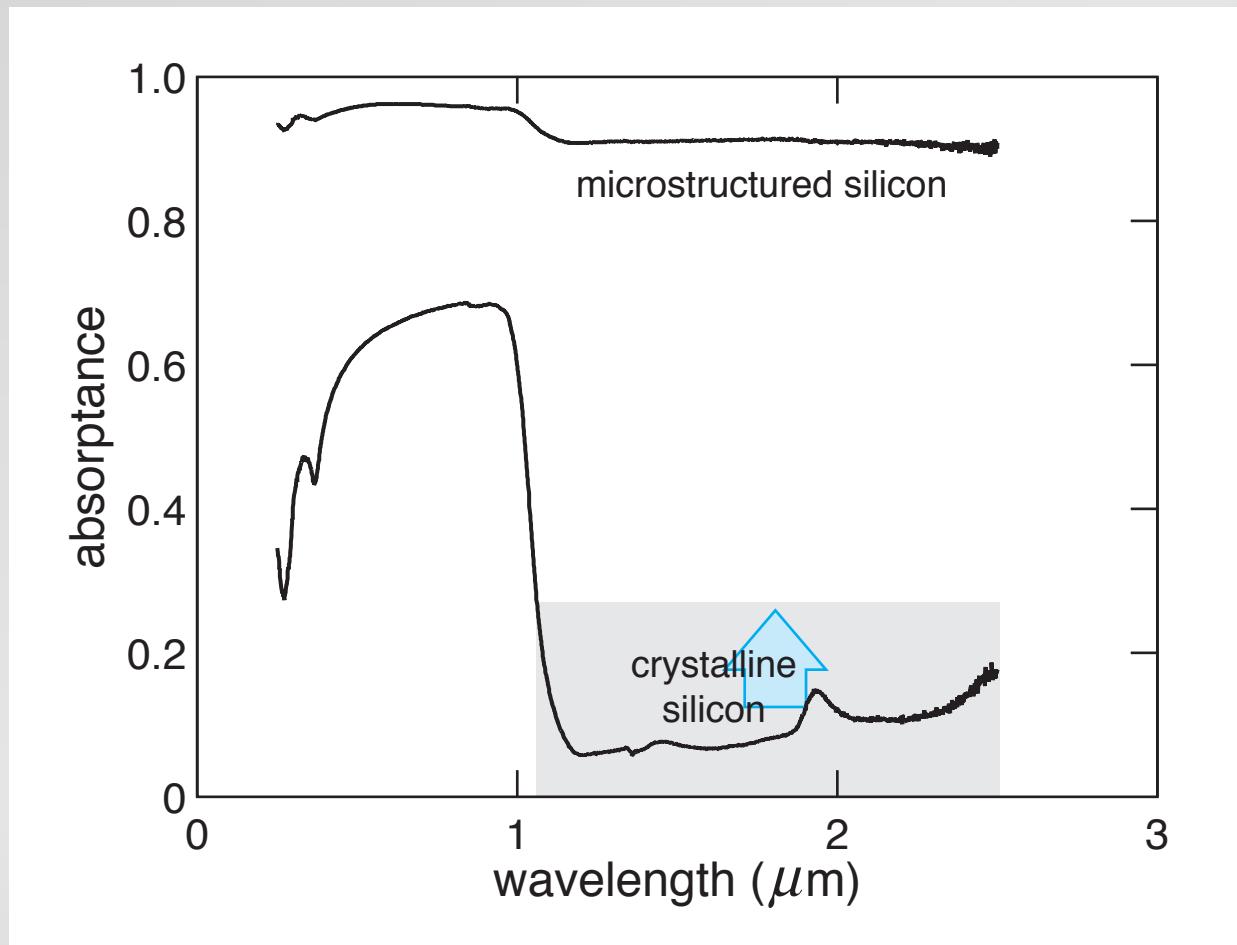
Properties

multiple reflections enhance absorption



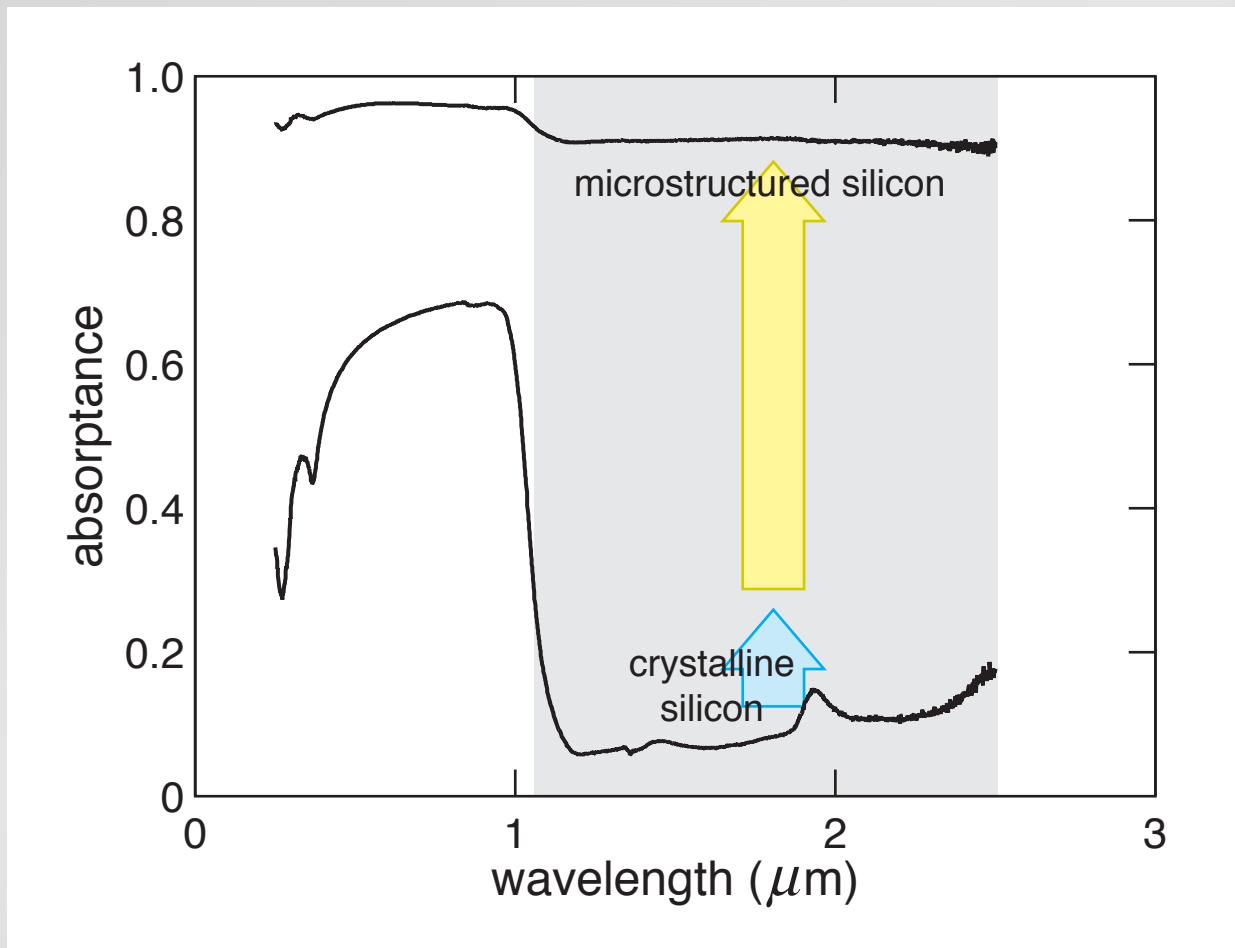
Properties

multiple reflections enhance absorption



Properties

electronic band structure changes



Properties

- enhanced absorption in visible
- enhanced photoelectron generation in visible
- near unity absorption in IR
- visible photoluminescence
- strong field emission

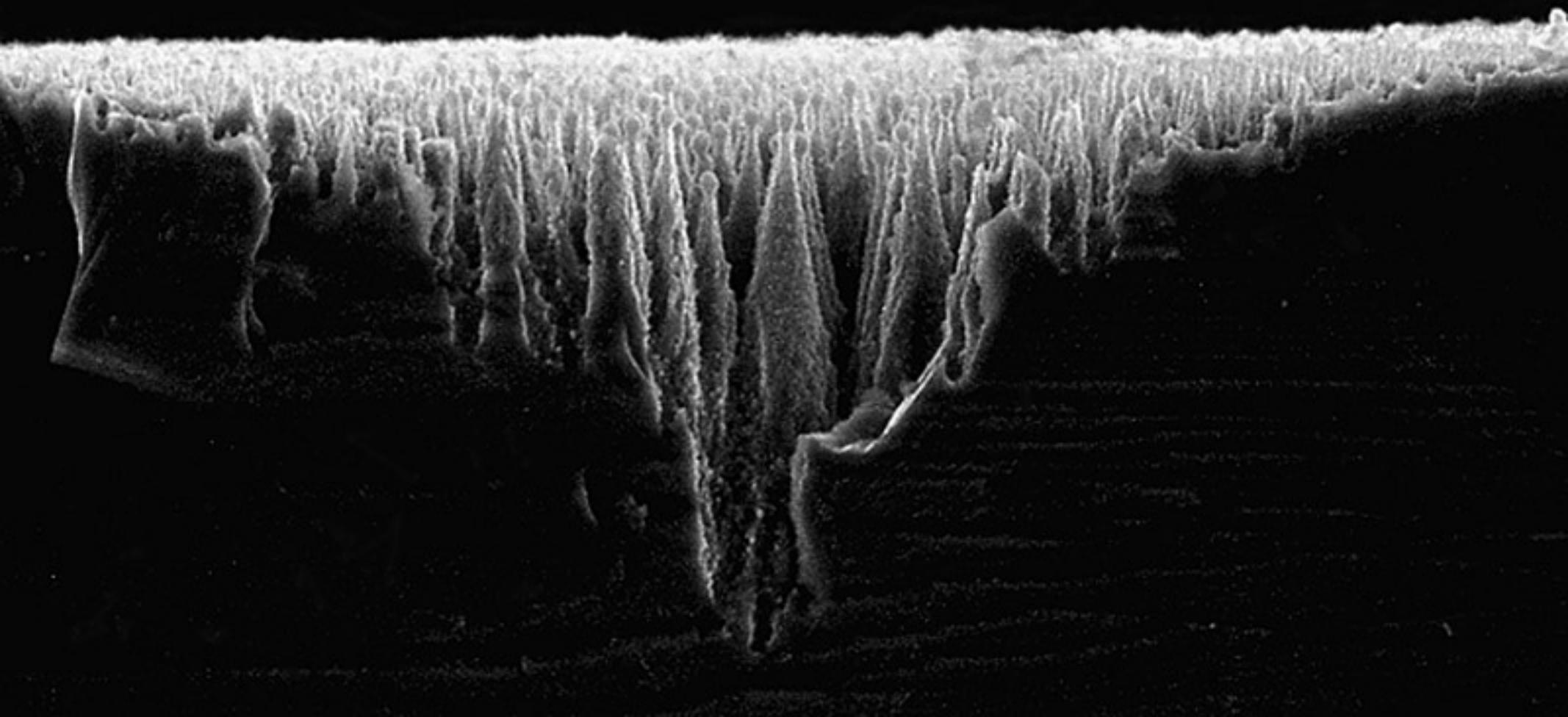
Outline

- properties
- structural and chemical analysis
- detectors
- outlook

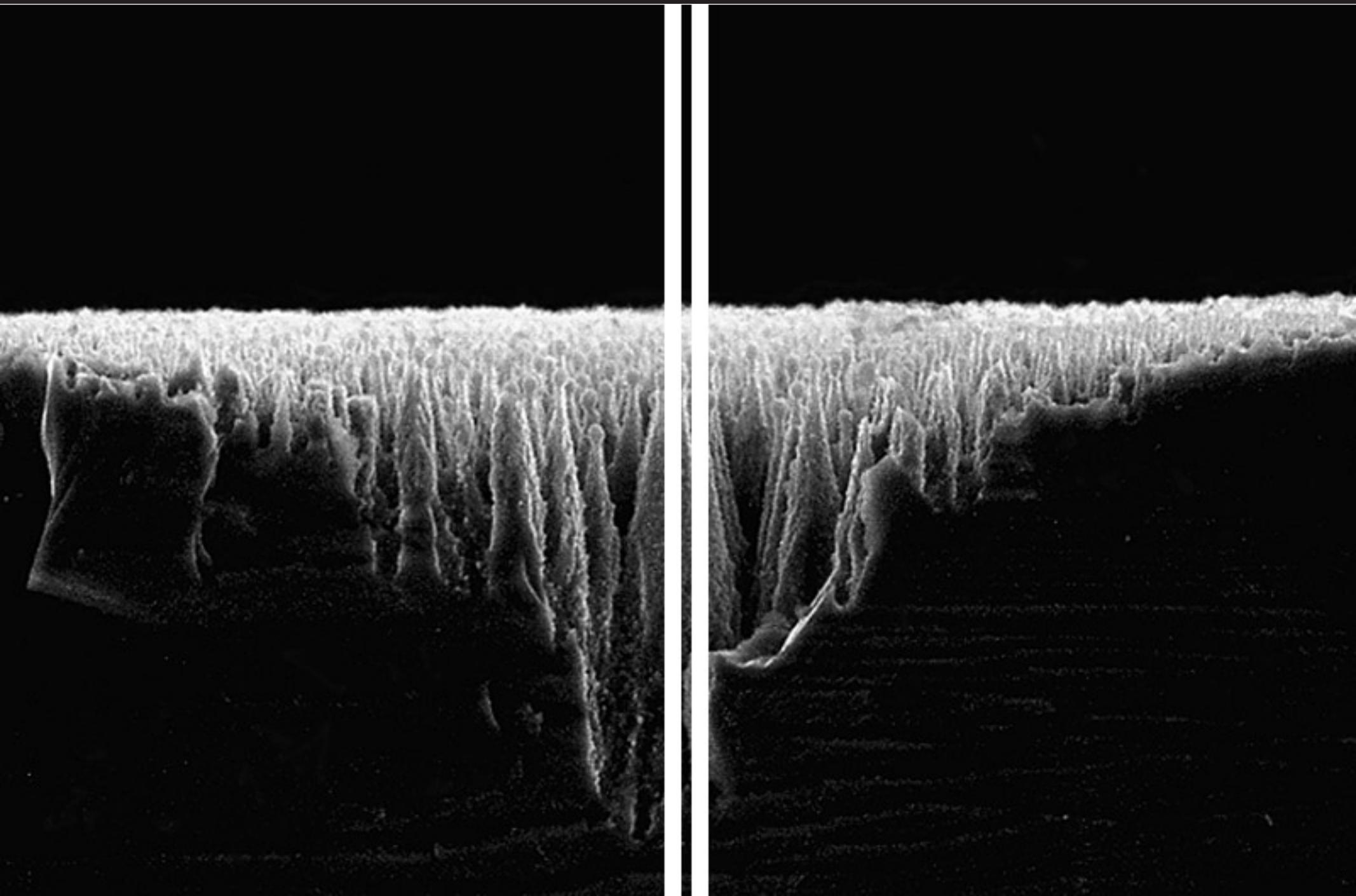
Structural and chemical analysis

Band structure changes: defects and/or impurities

Structural and chemical analysis



Structural and chemical analysis



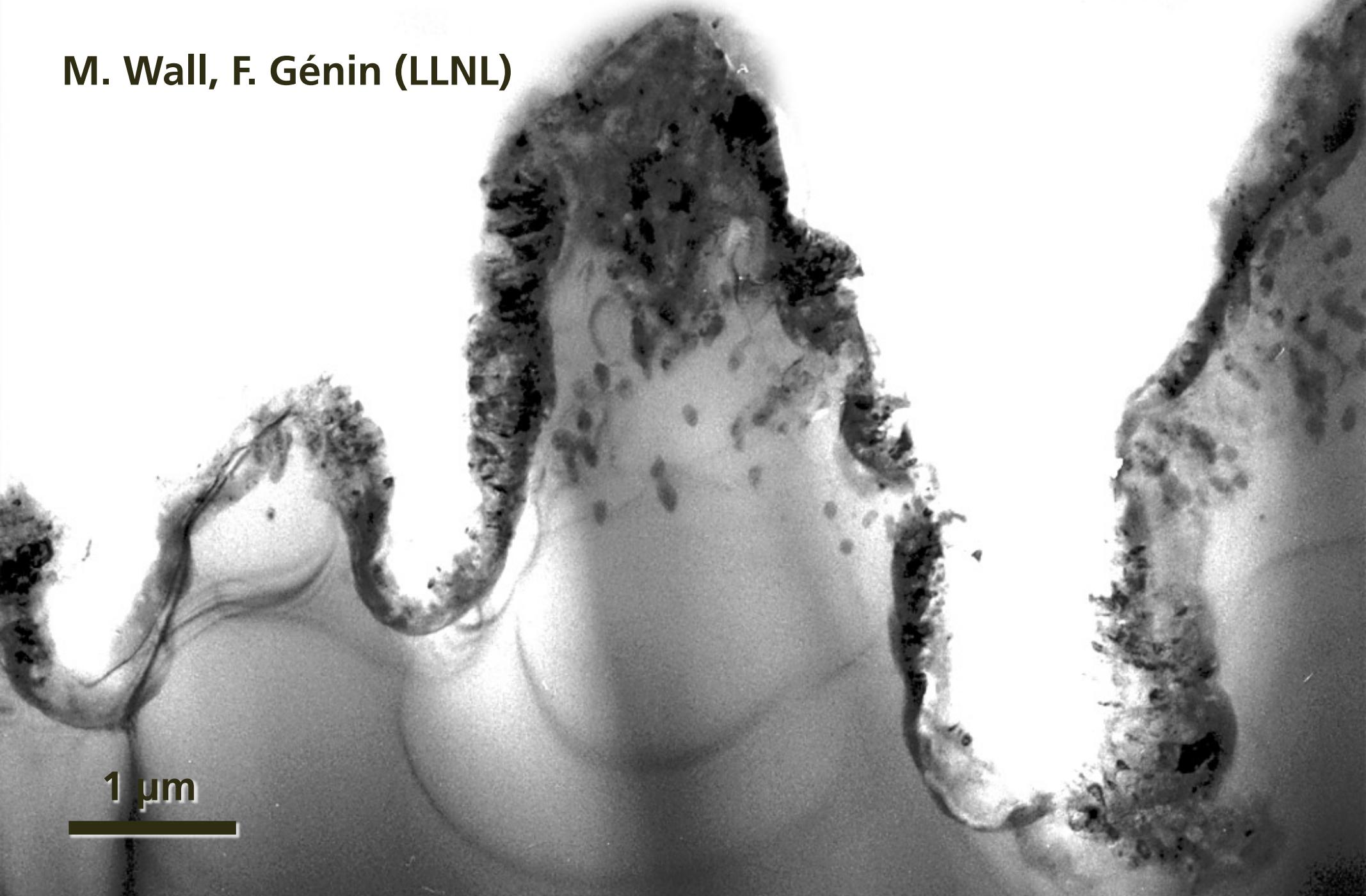
Structural and chemical analysis

**cross-sectional
Transmission Electron
Microscopy**



Structural and chemical analysis

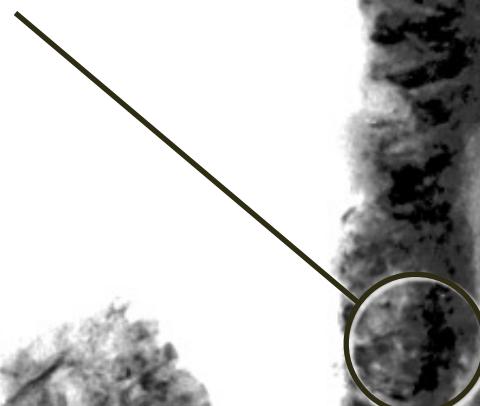
M. Wall, F. Génin (LLNL)



1 μm

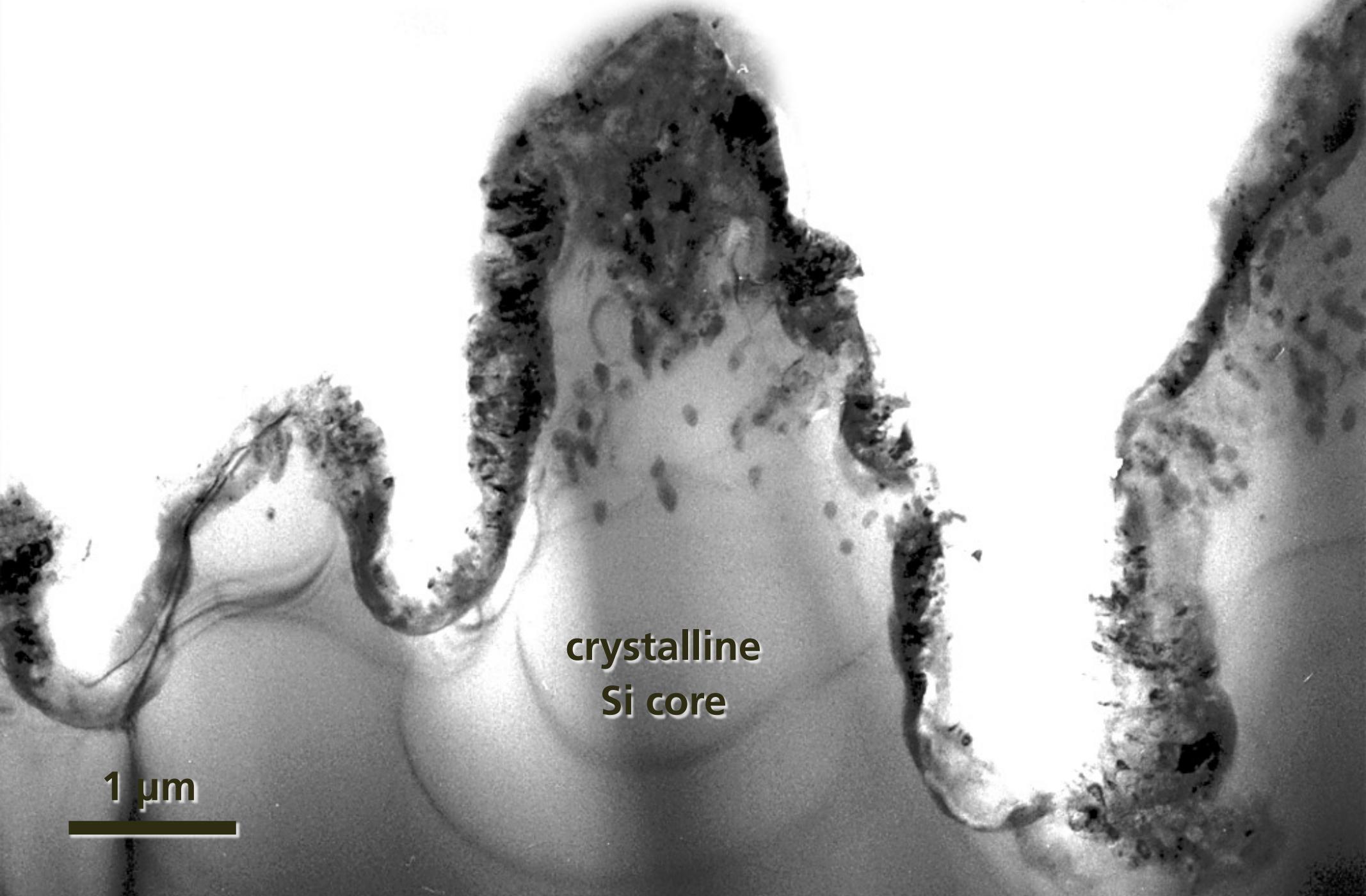
Structural and chemical analysis

disordered
surface layer

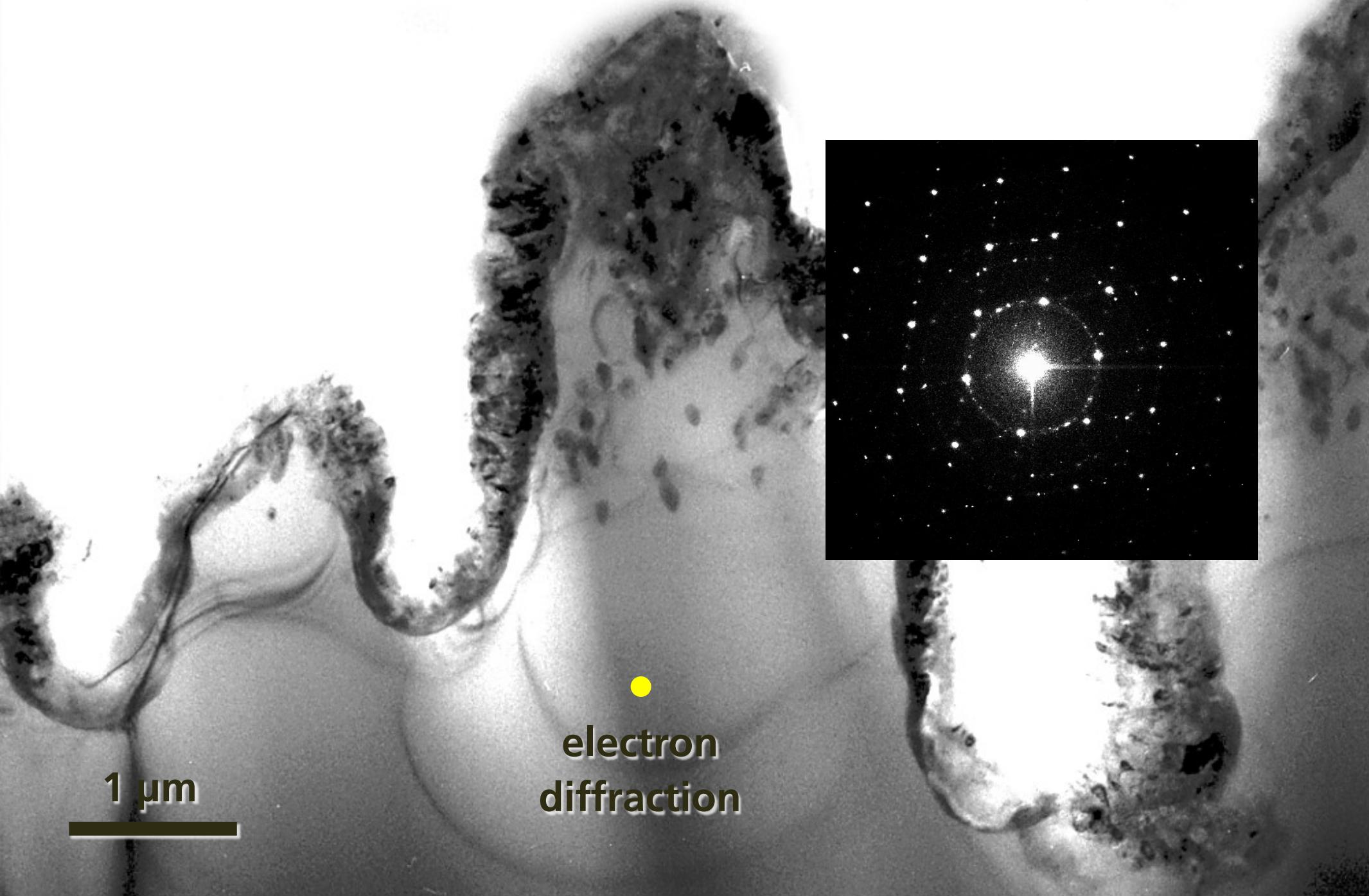


1 μm

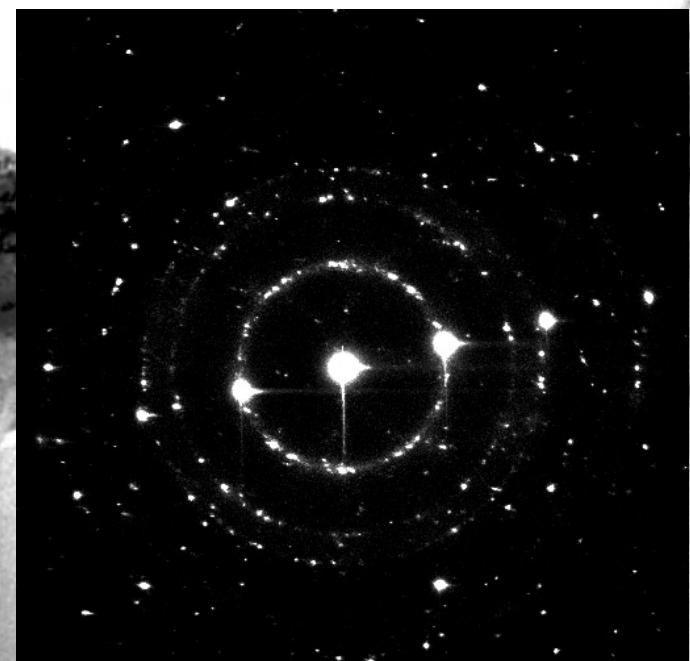
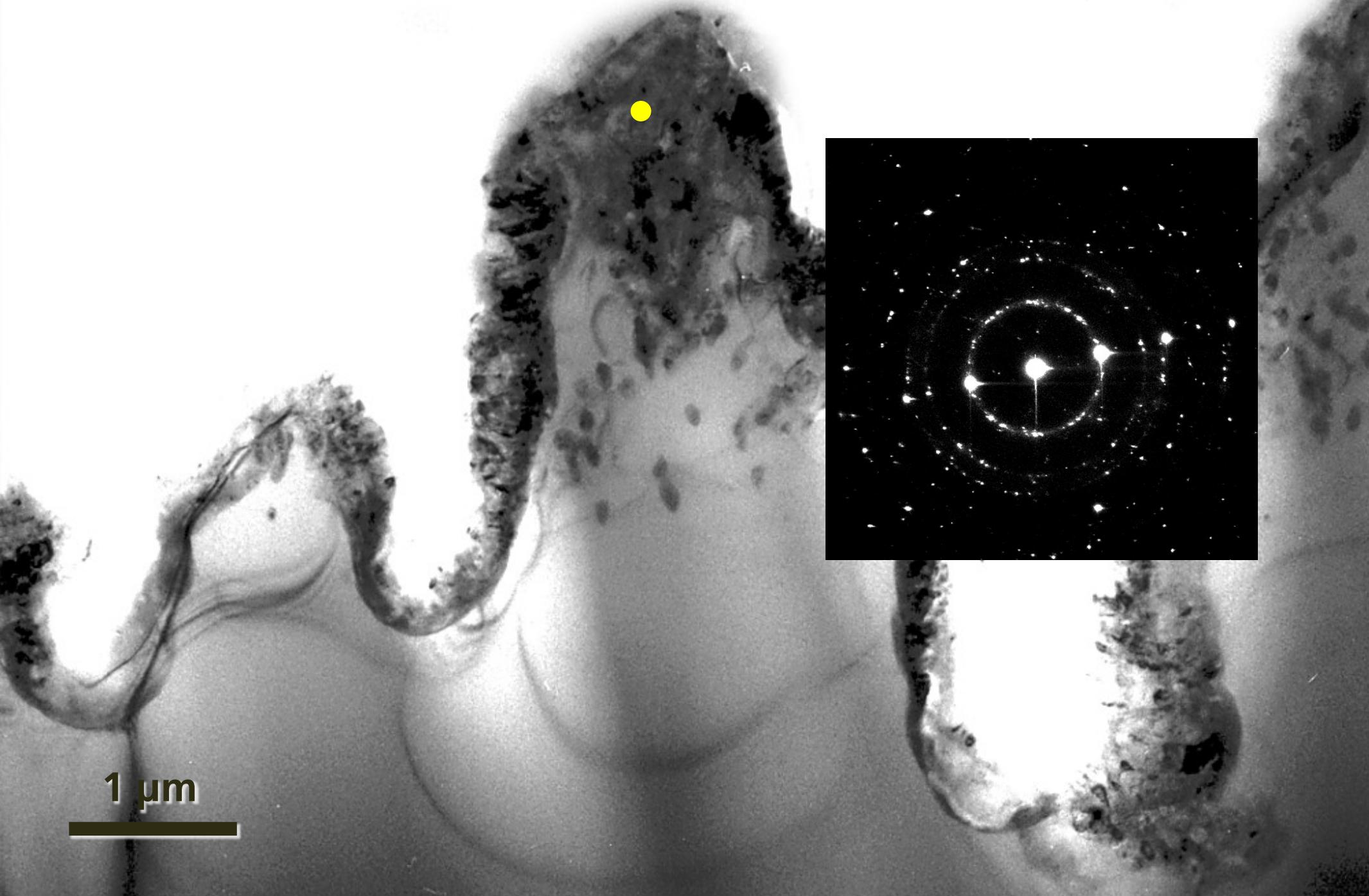
Structural and chemical analysis



Structural and chemical analysis



Structural and chemical analysis



Structural and chemical analysis

- 100-nm disordered surface layer
- undisturbed crystalline core
- surface layer: polycrystalline Si with 1.6% sulfur

1 μm

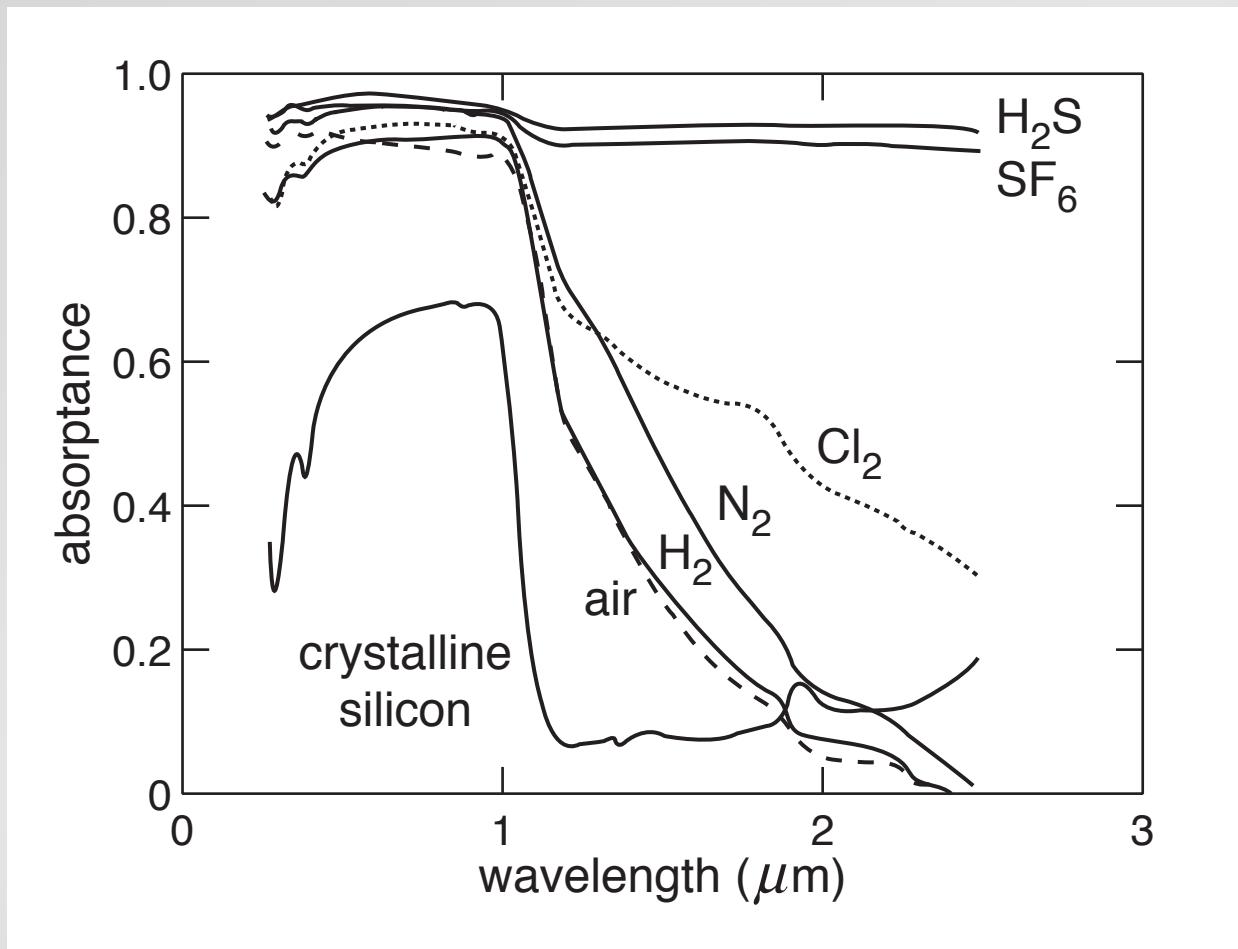
Structural and chemical analysis

Microstructure with different gases:

- **gas species incorporated into surface layer**
- **sulfur required for below band gap absorption**

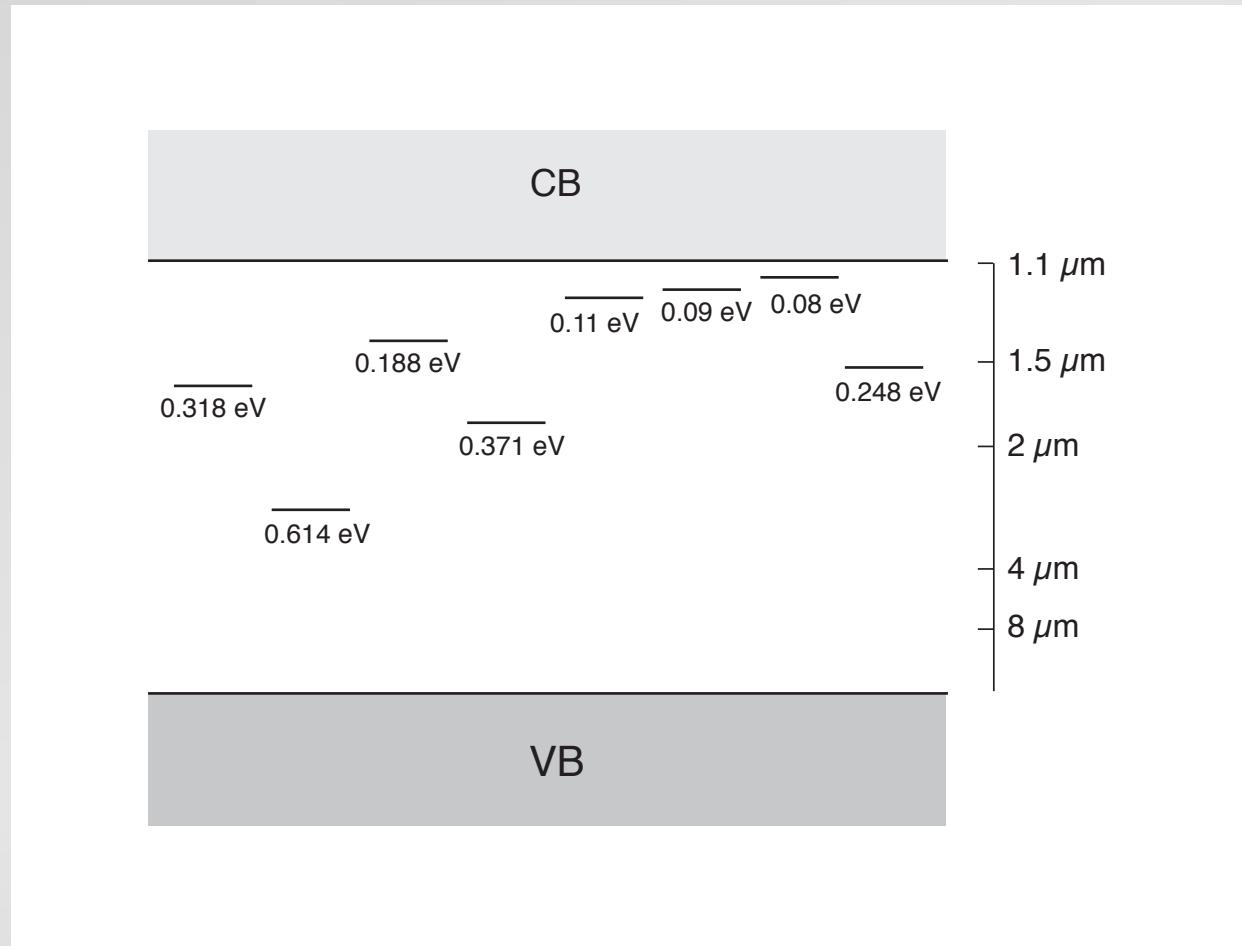
Structural and chemical analysis

microstructure with different gases



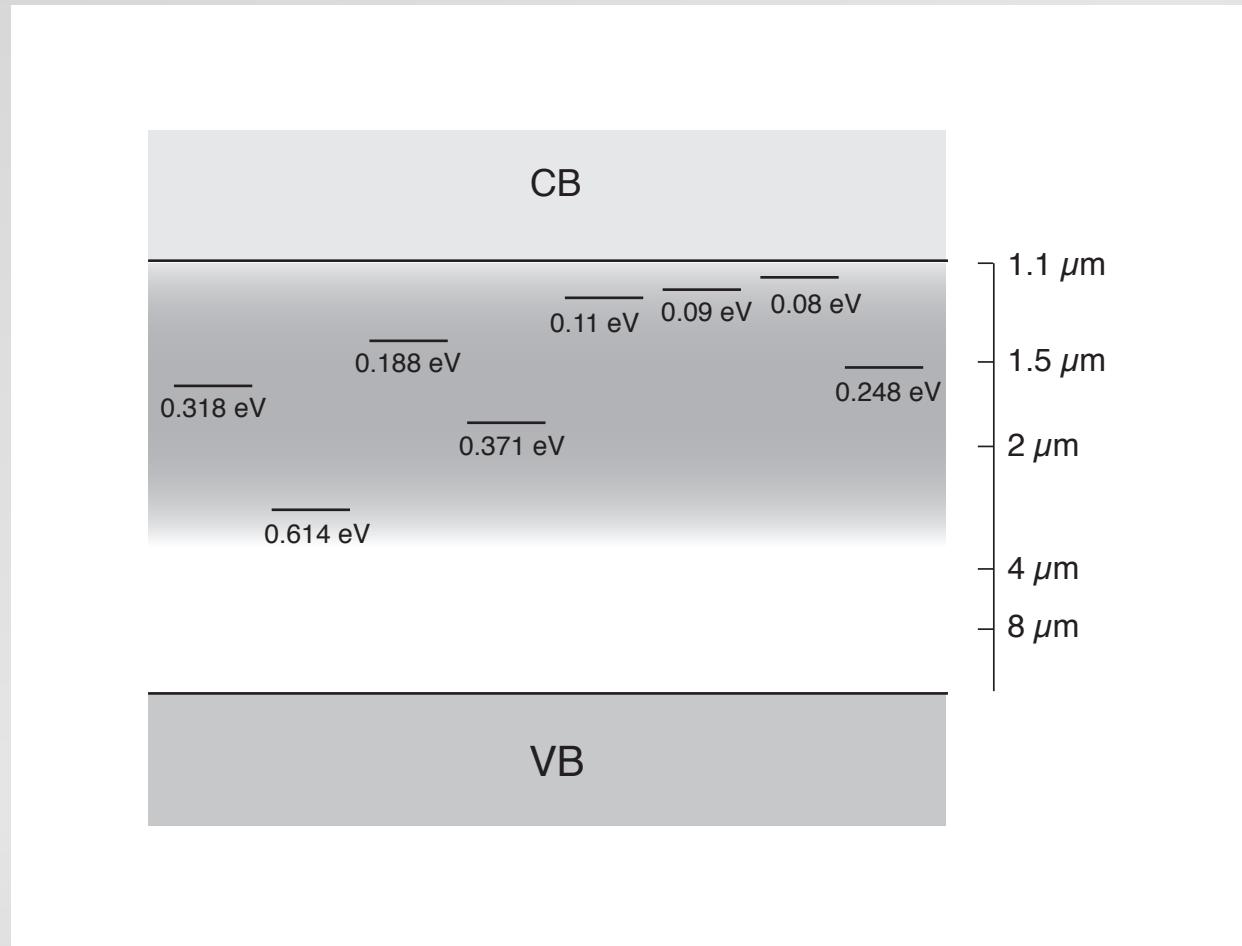
Structural and chemical analysis

1 part in 10^6 sulfur introduces states in gap



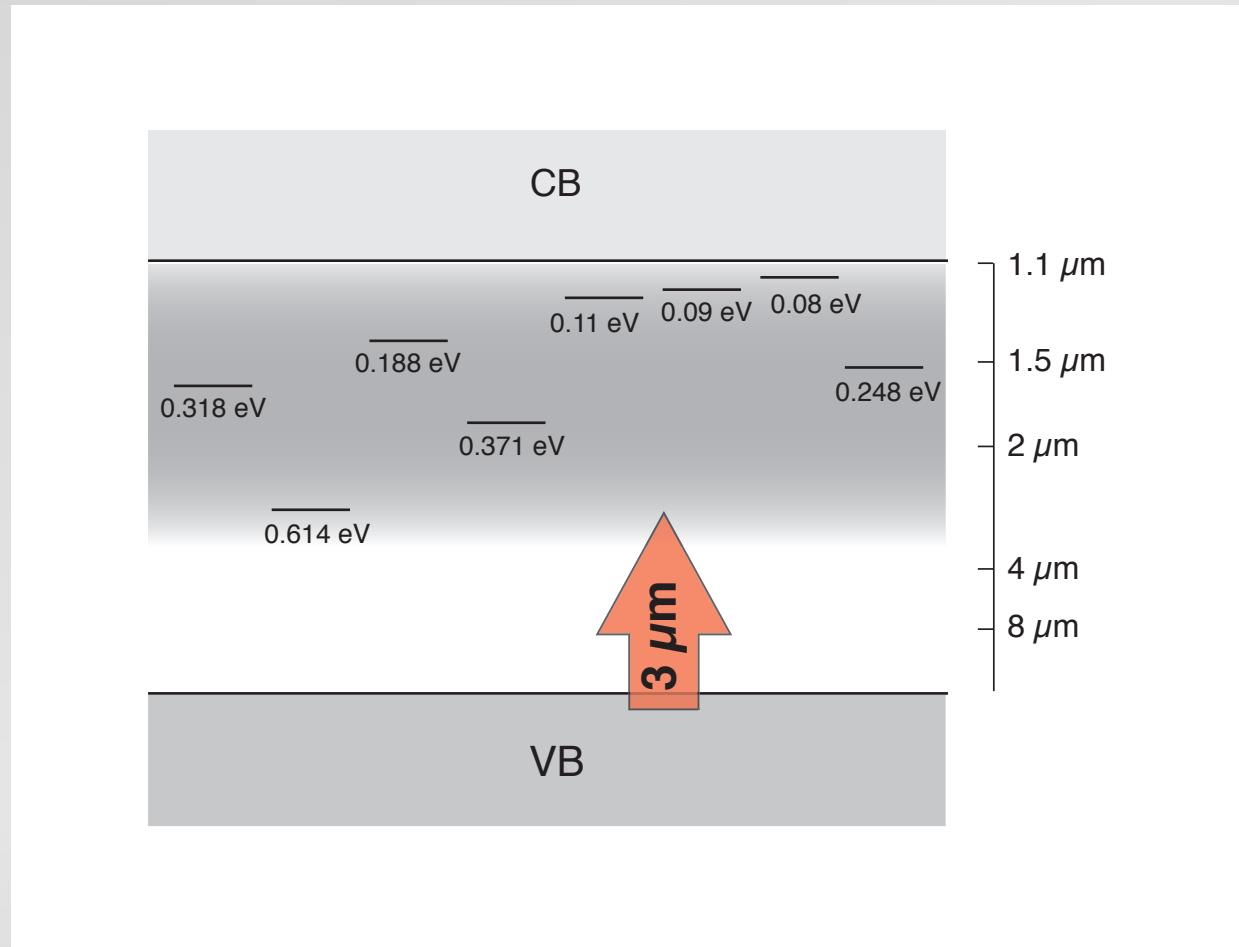
Structural and chemical analysis

at high concentration states broaden into band



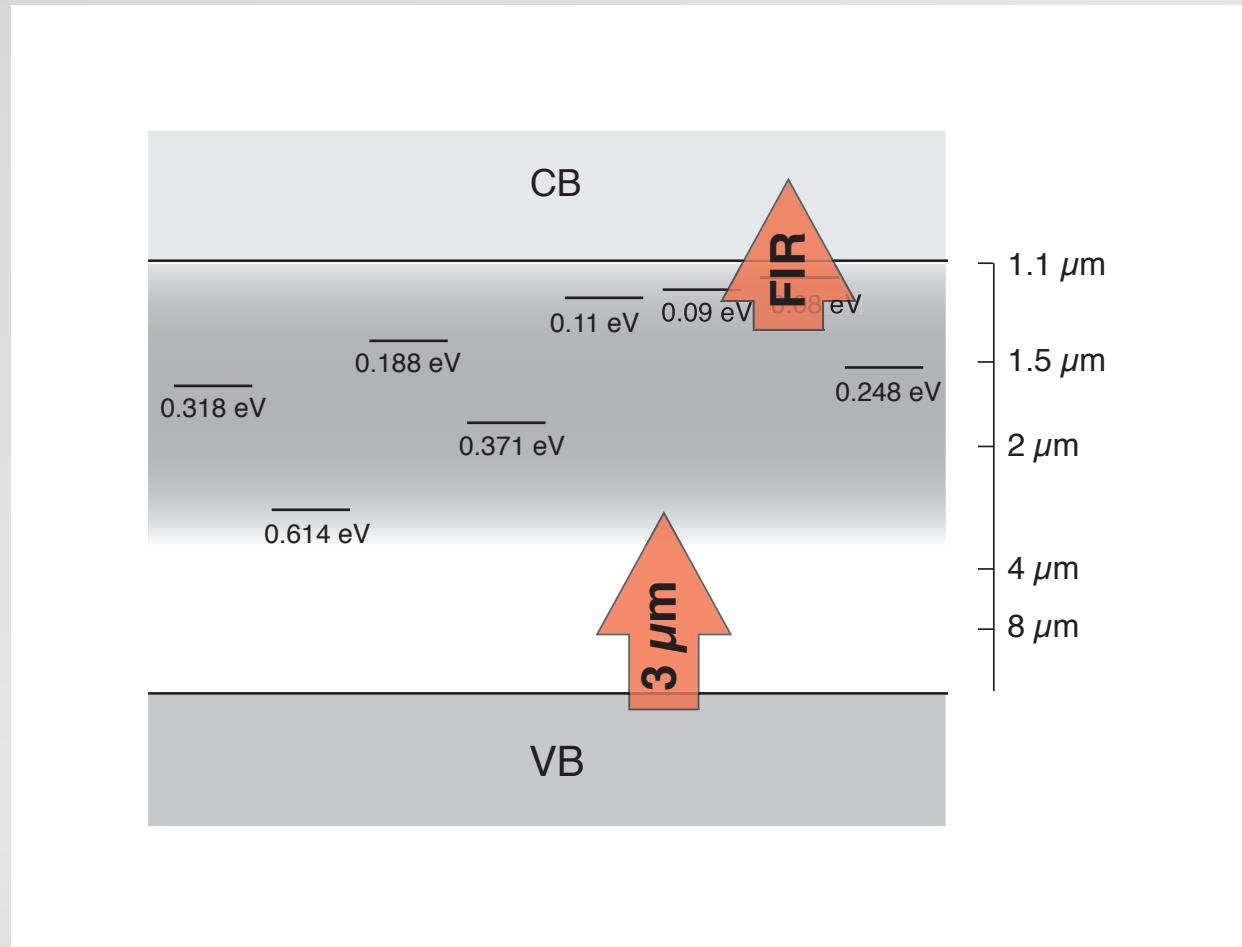
Structural and chemical analysis

absorption extends into infrared



Structural and chemical analysis

sulfur has 6 valence electrons: donor states?

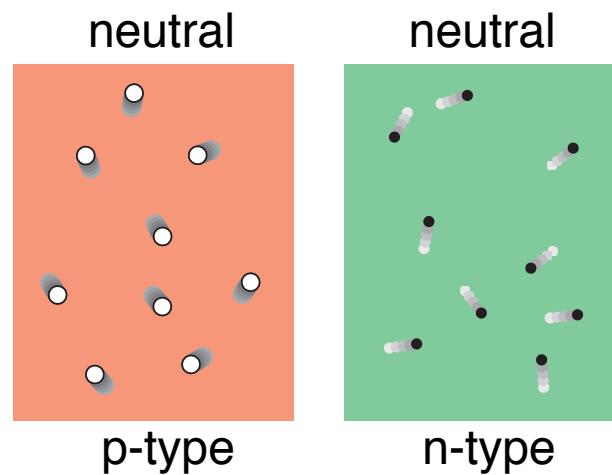


Outline

- properties
- structural and chemical analysis
- detectors
- outlook

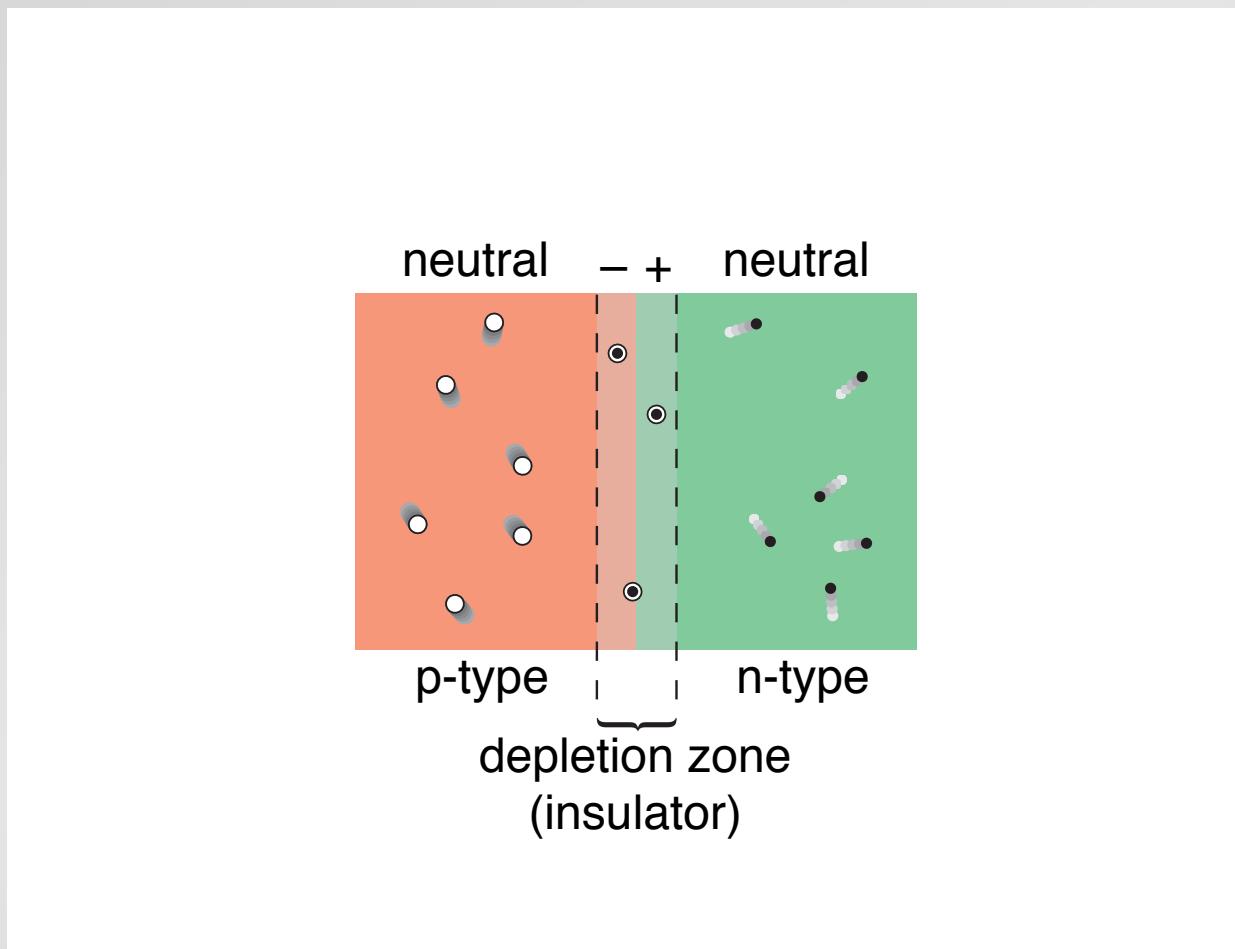
Detectors

join acceptor and donor type Si



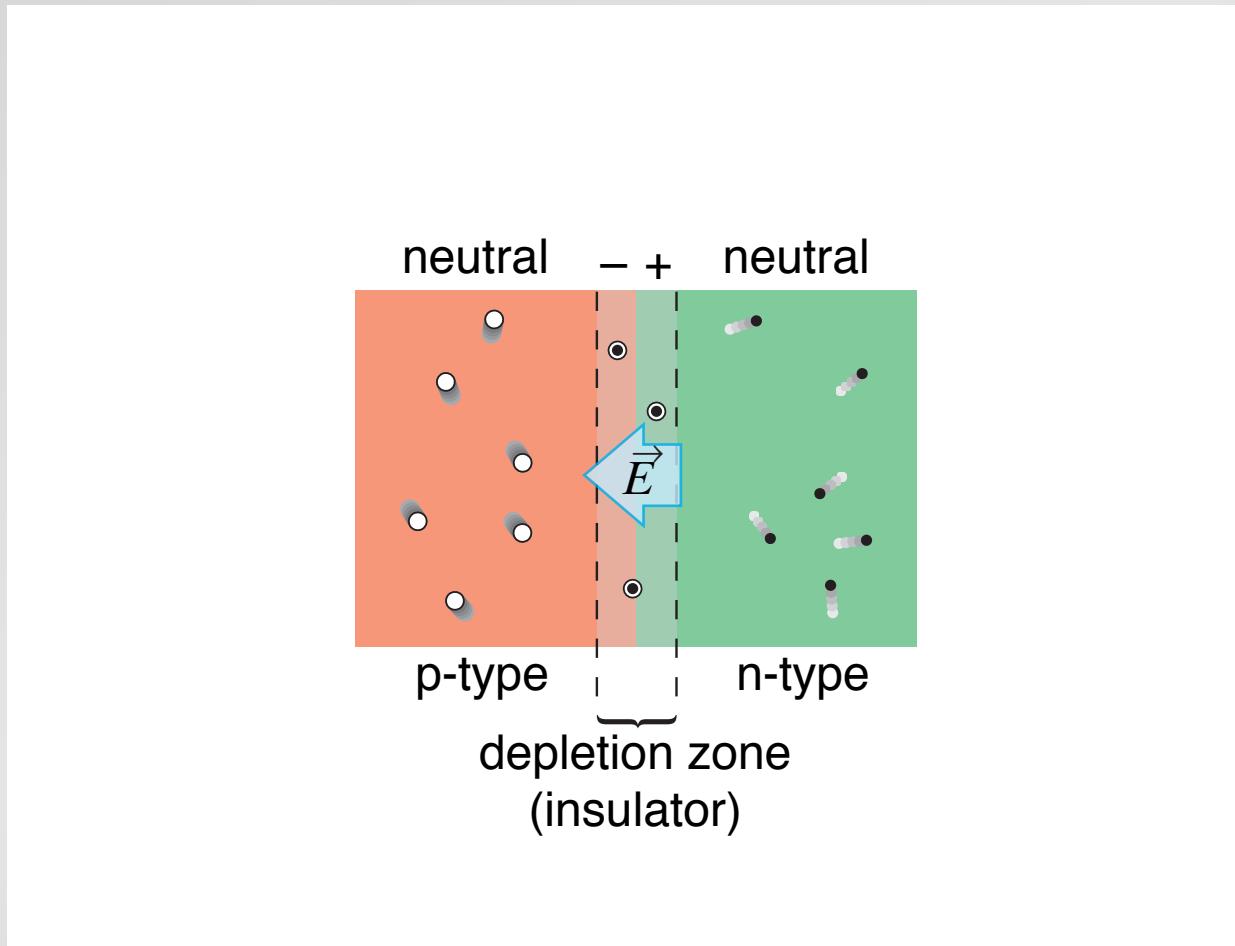
Detectors

join acceptor and donor type Si



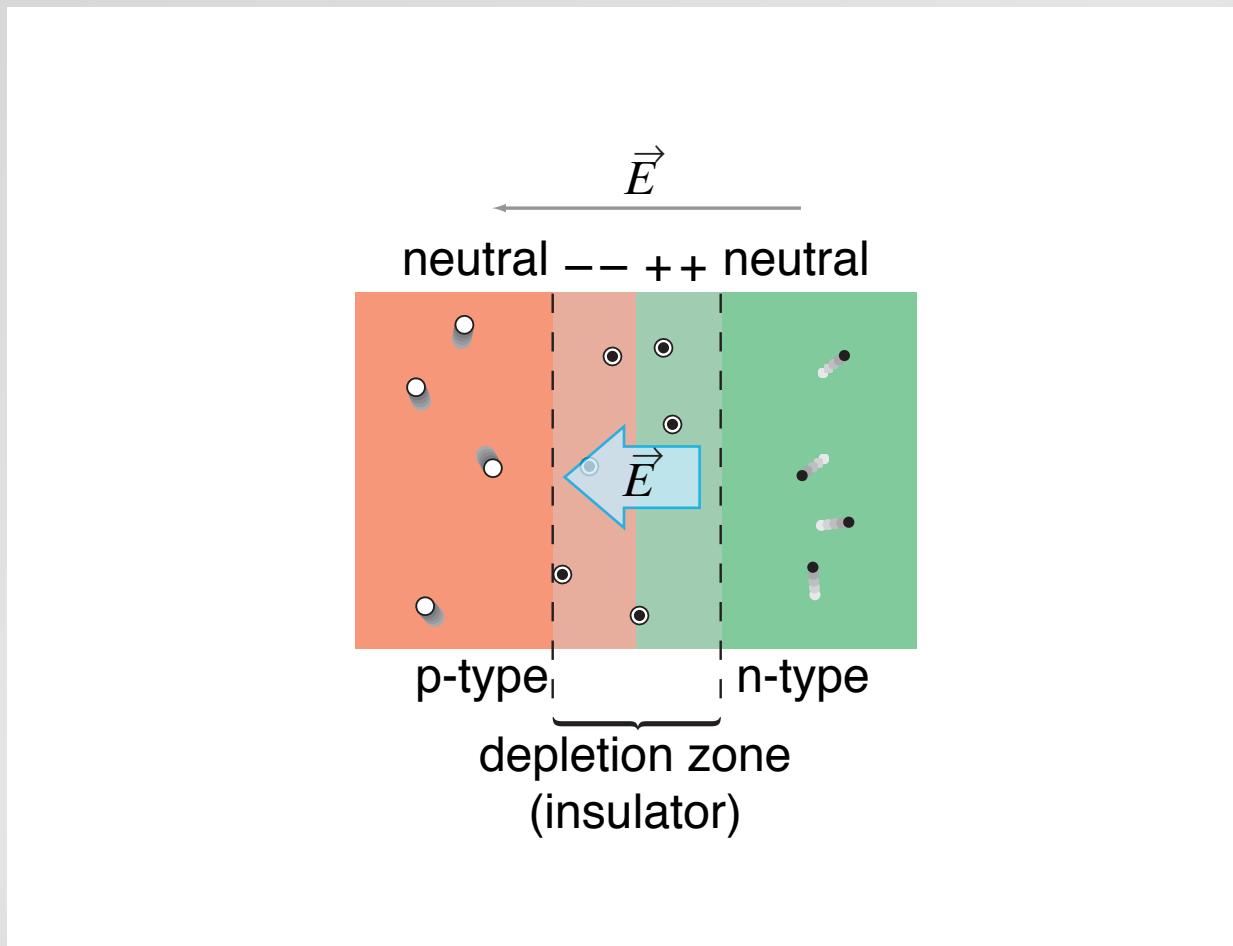
Detectors

depletion zone with strong E-field



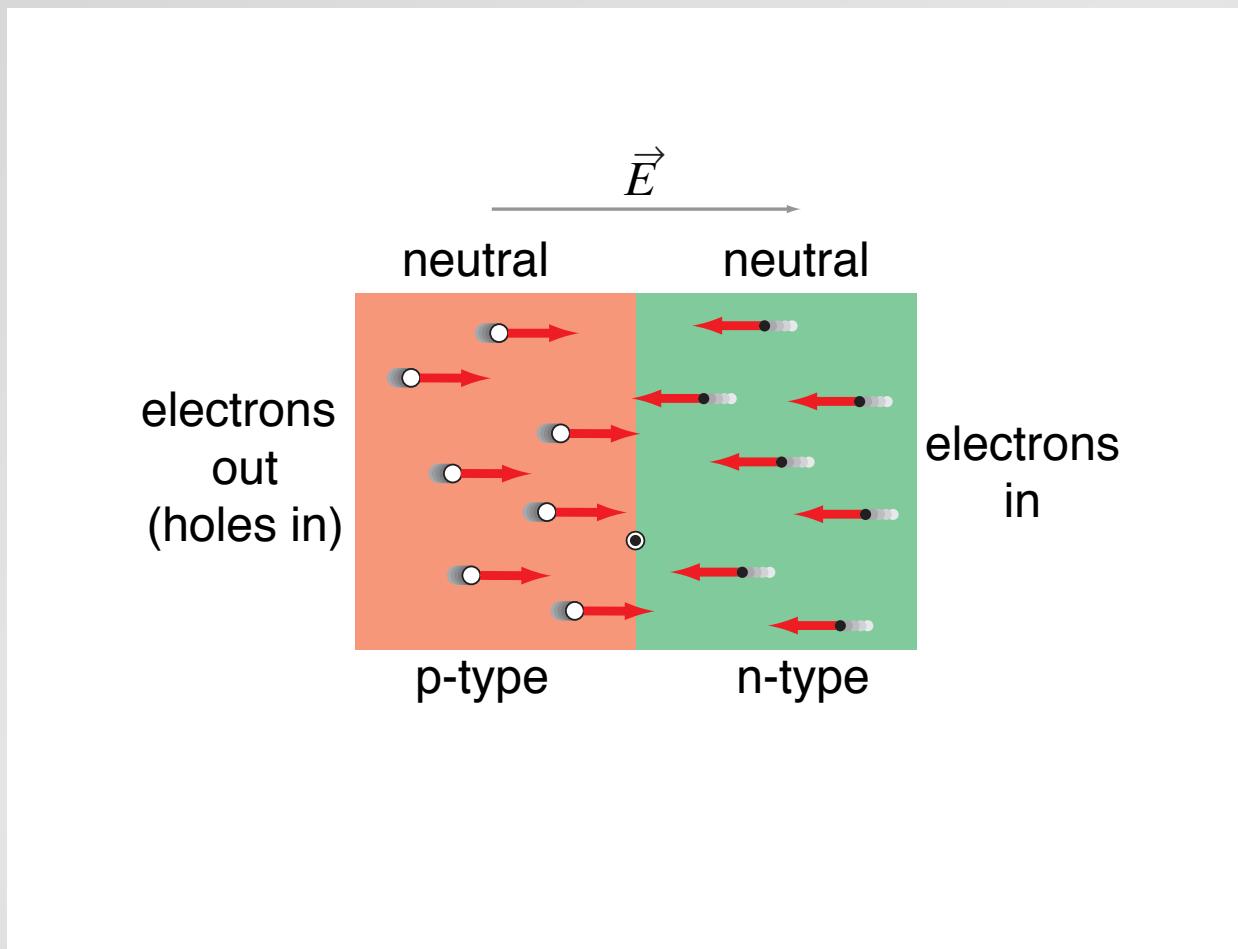
Detectors

reverse bias: depletion zone grows



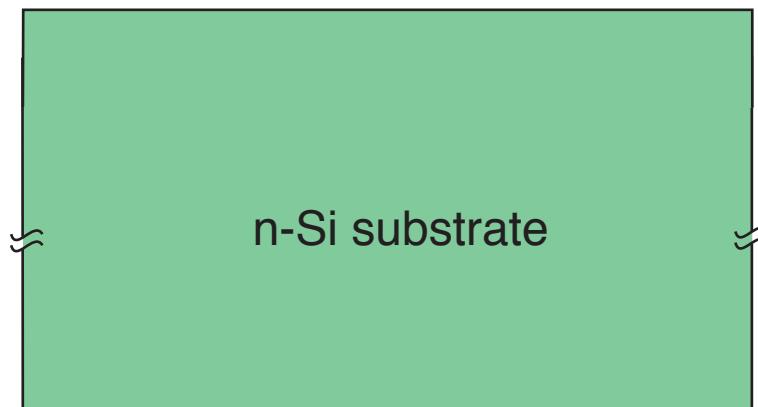
Detectors

forward bias: current flows



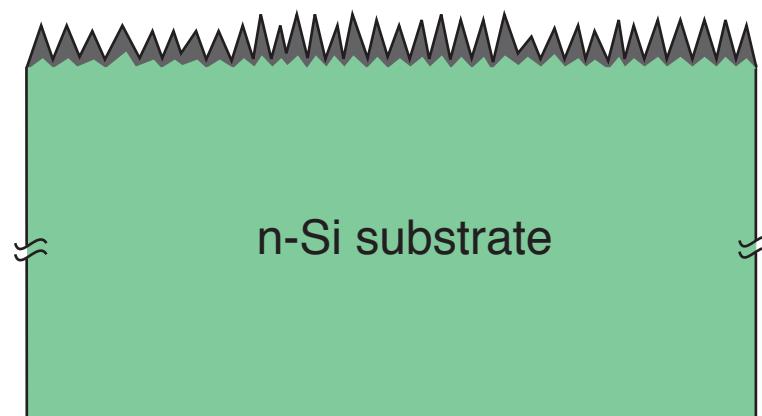
Detectors

black silicon/n-type silicon junction



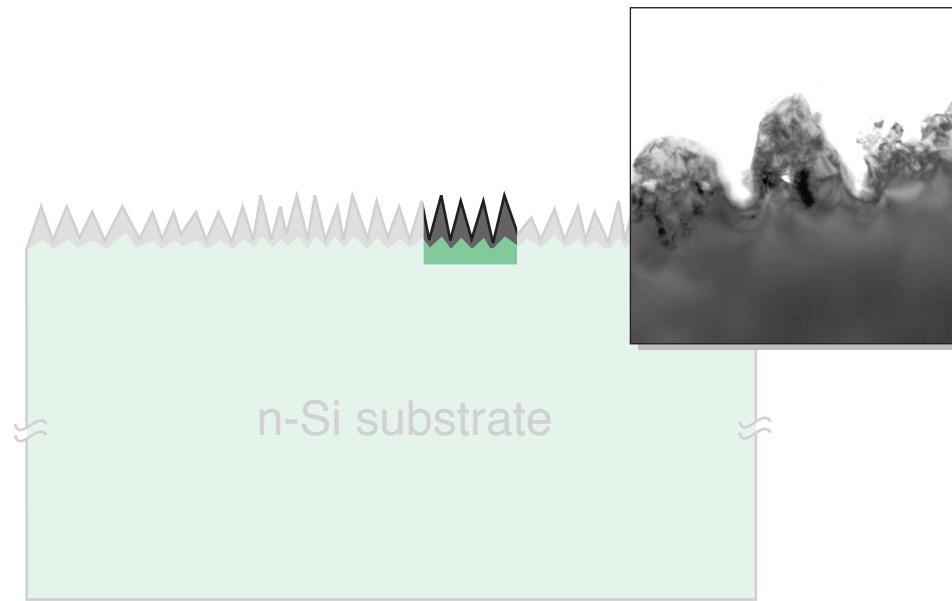
Detectors

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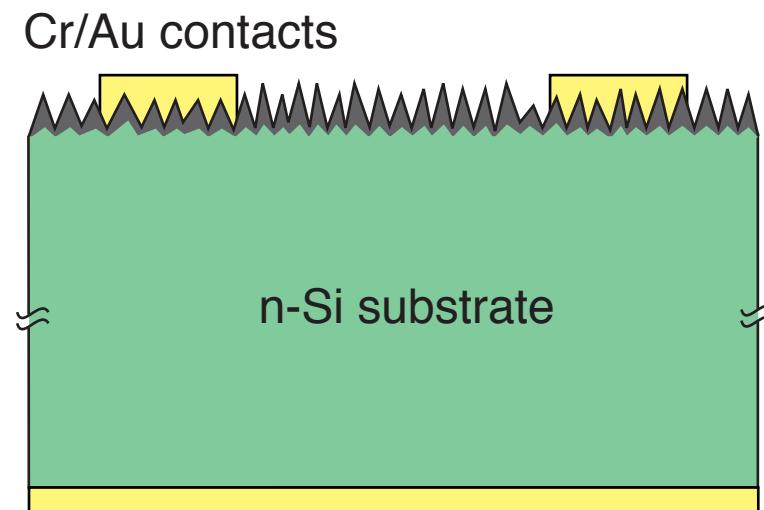
Detectors

black silicon/n-type silicon junction



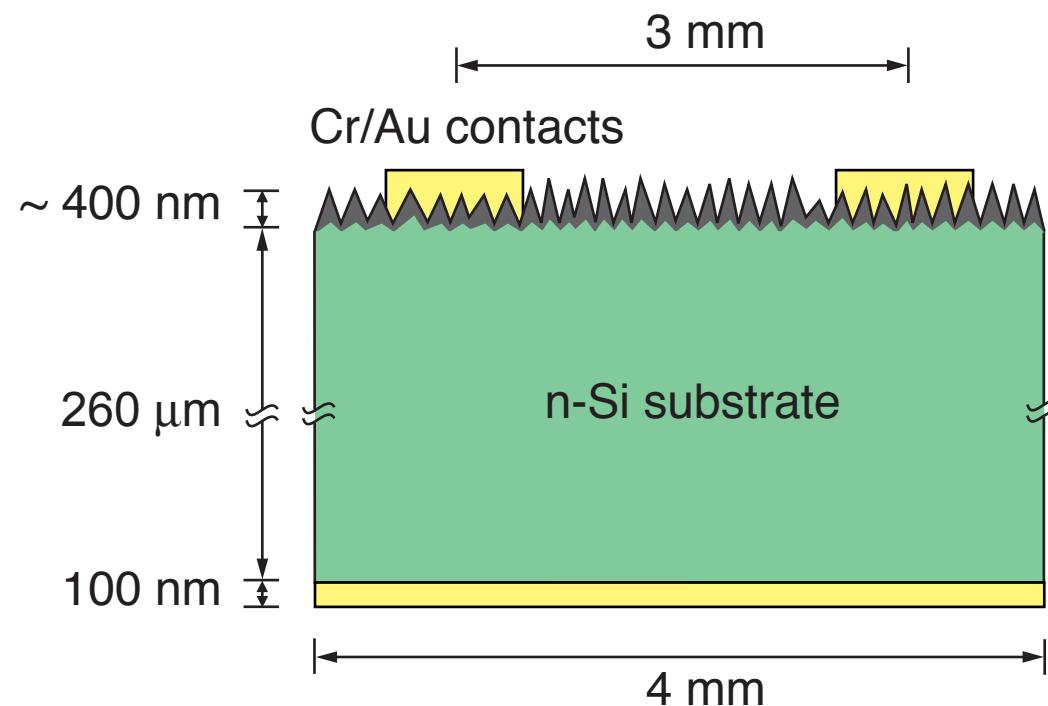
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black silicon/n-type silicon junction



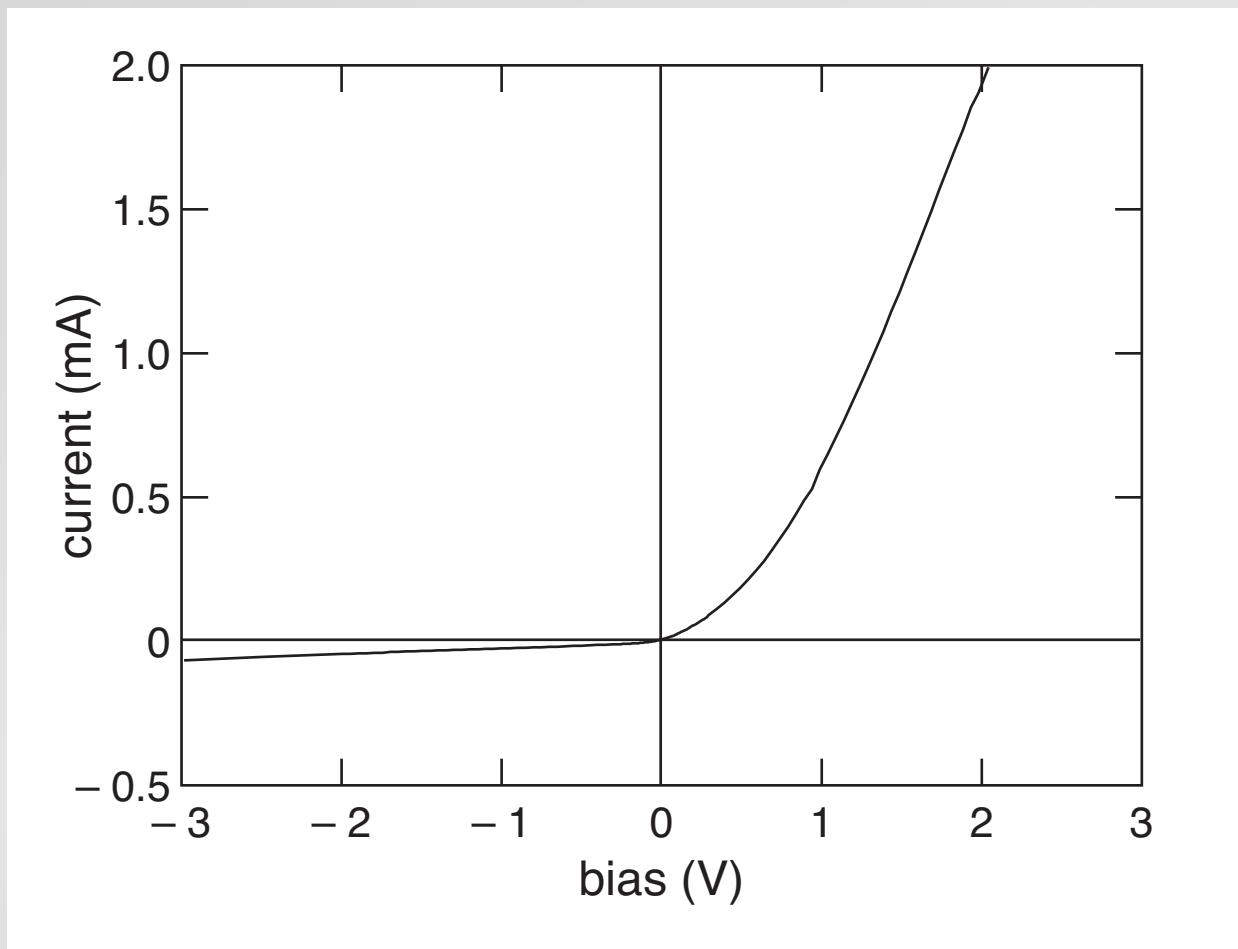
Detectors

black silicon/n-type silicon junction



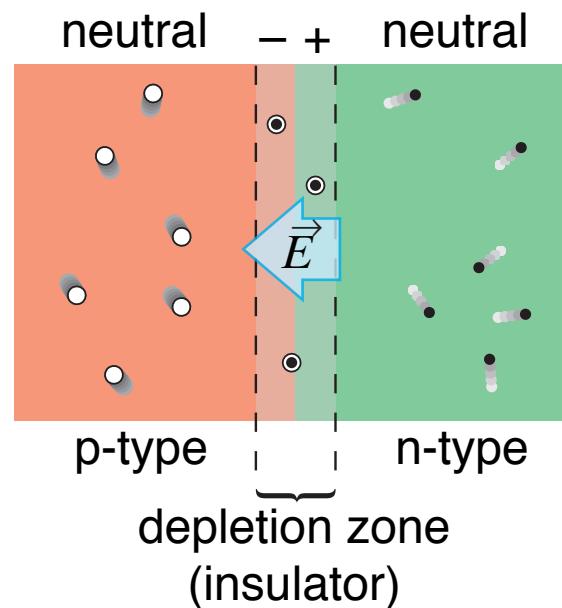
Detectors

IV characteristics



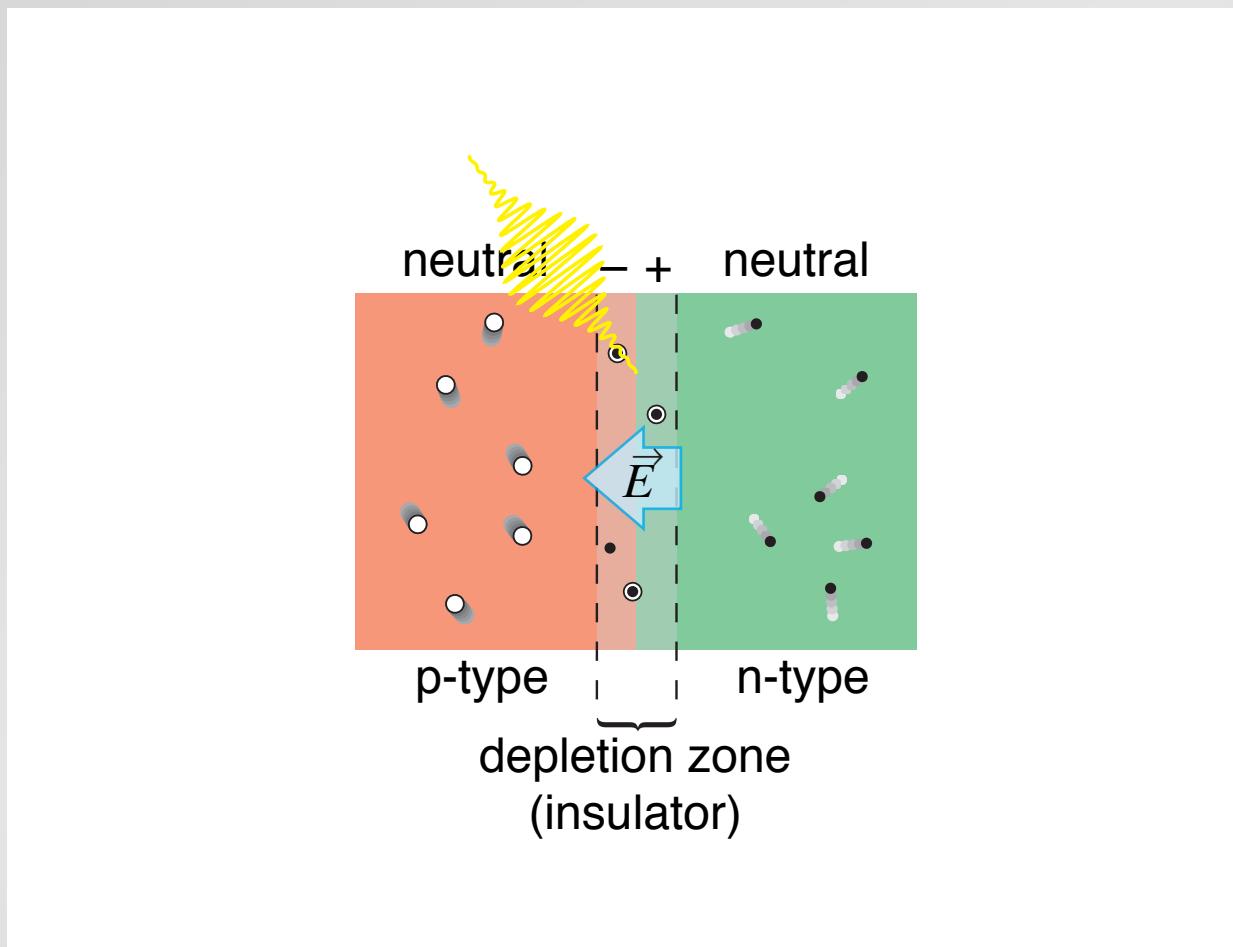
Detectors

photodiode operation



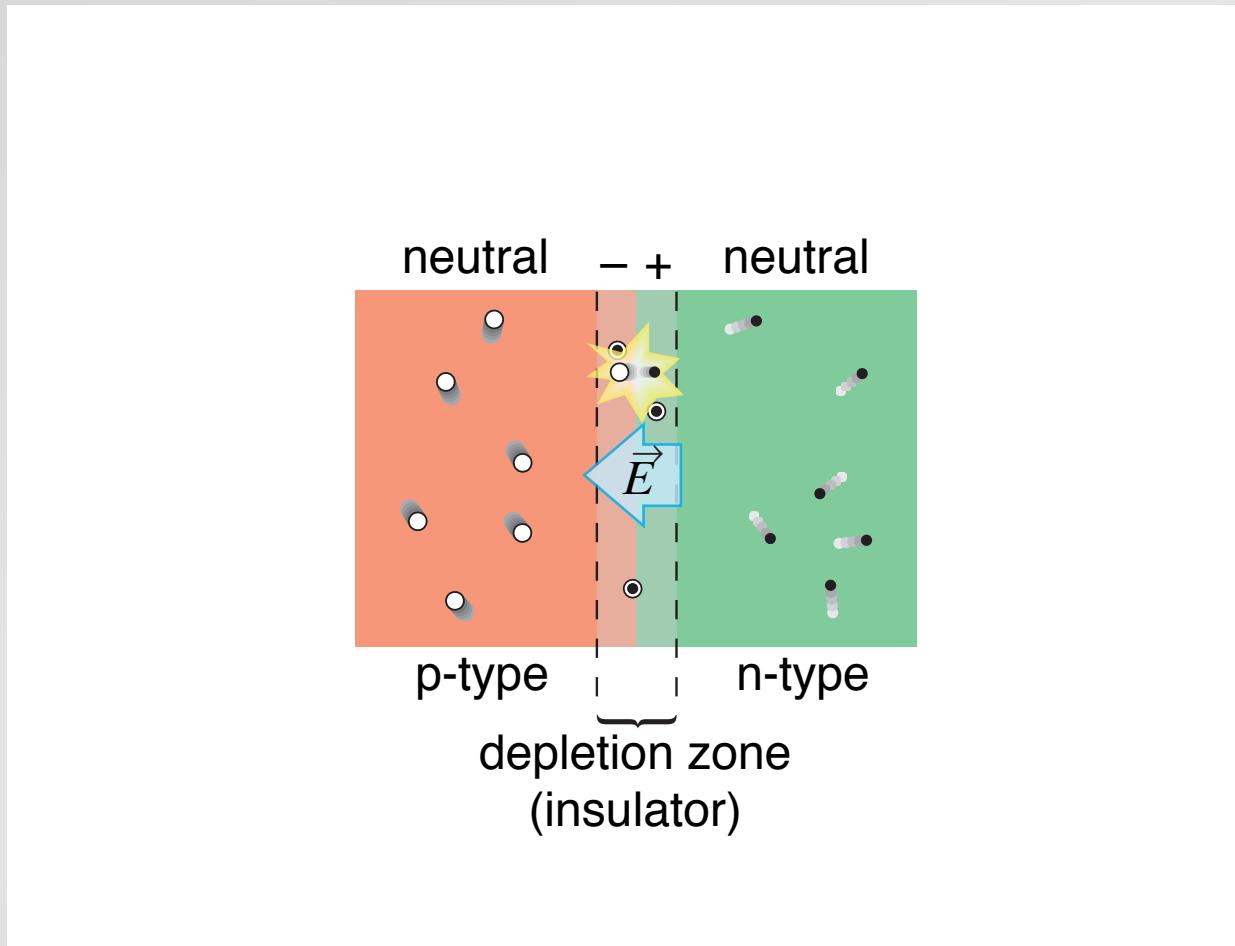
Detectors

photodiode operation



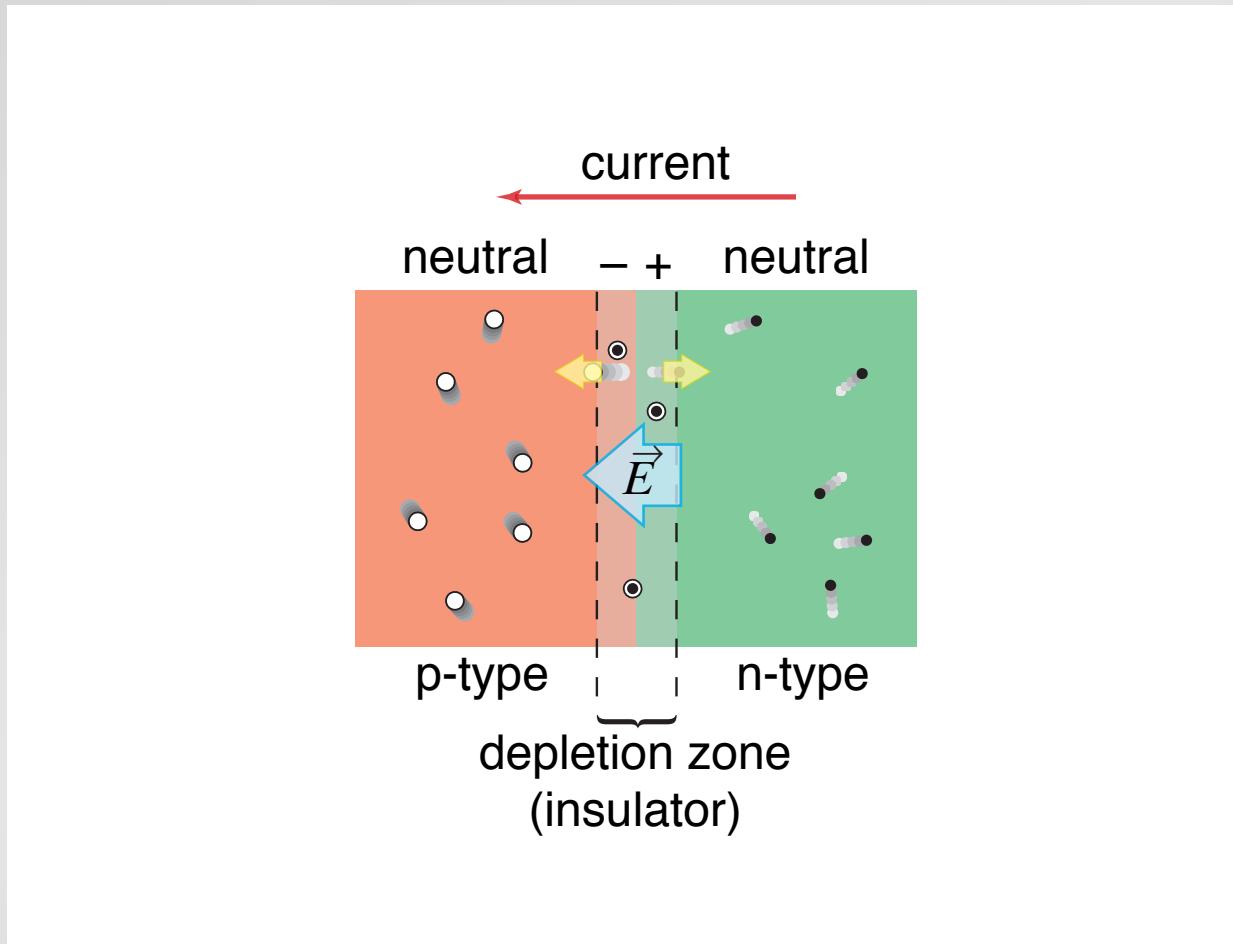
Detectors

incident photon creates electron-hole pair



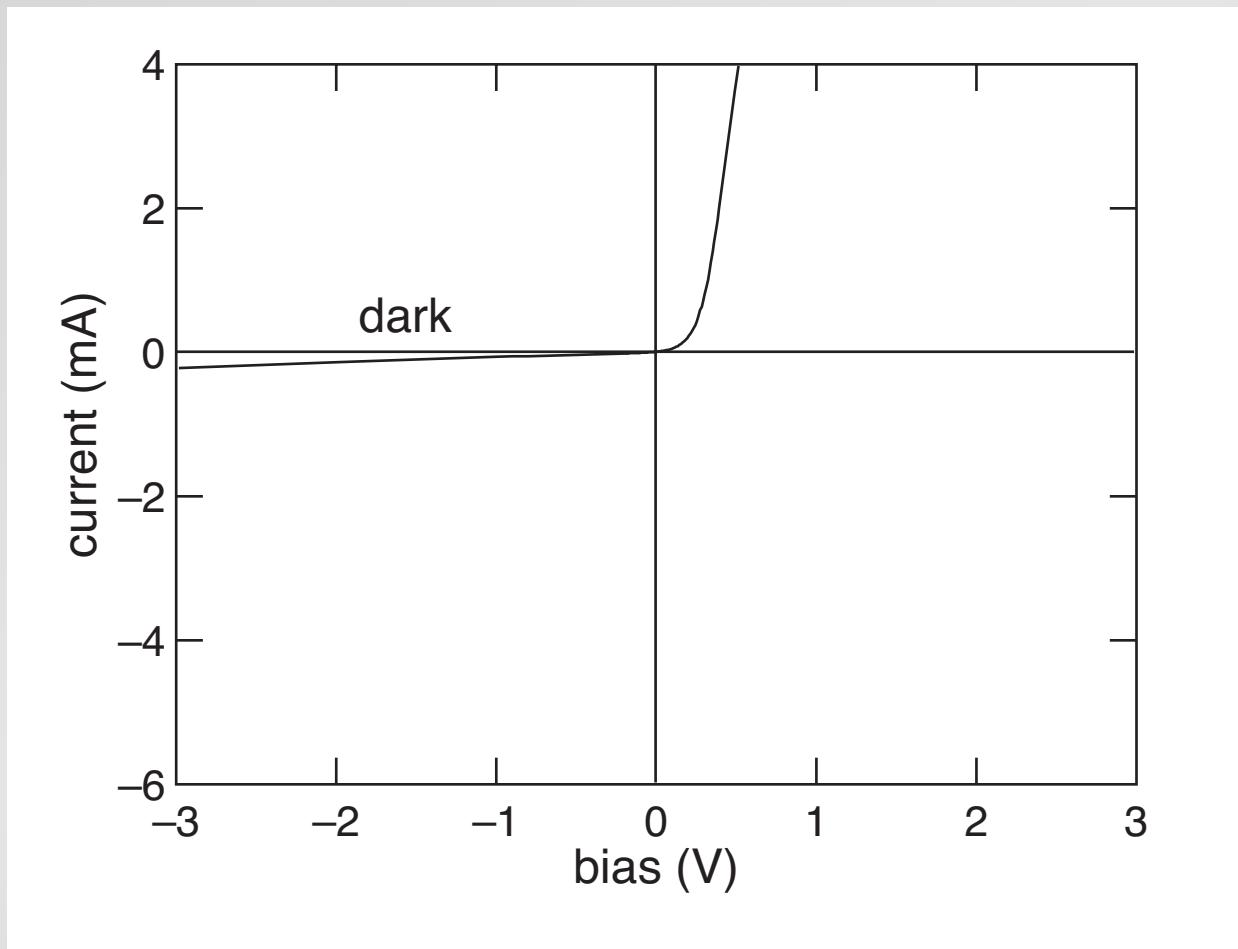
Detectors

E-field separates eh-pair causing current



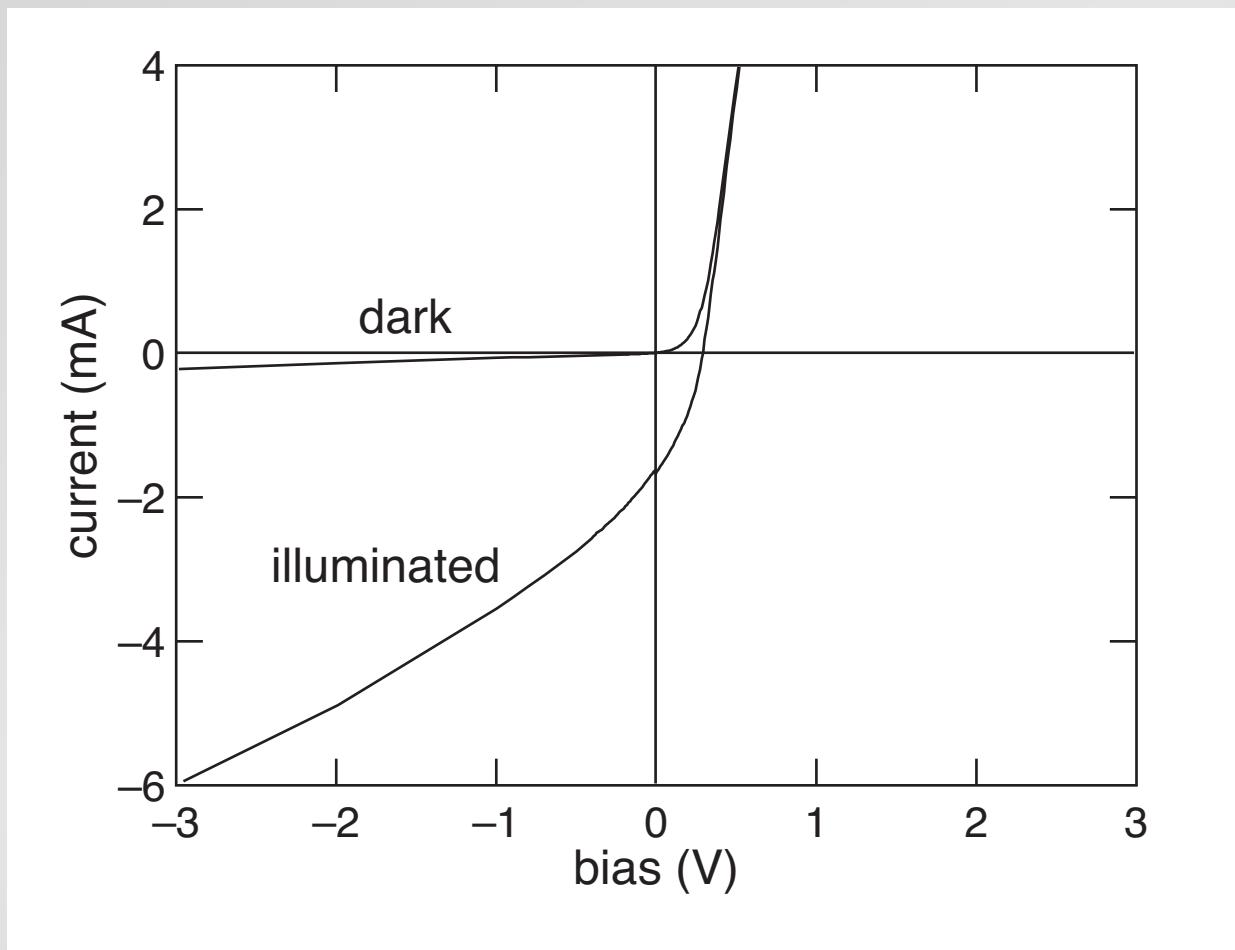
Detectors

I/V characteristics



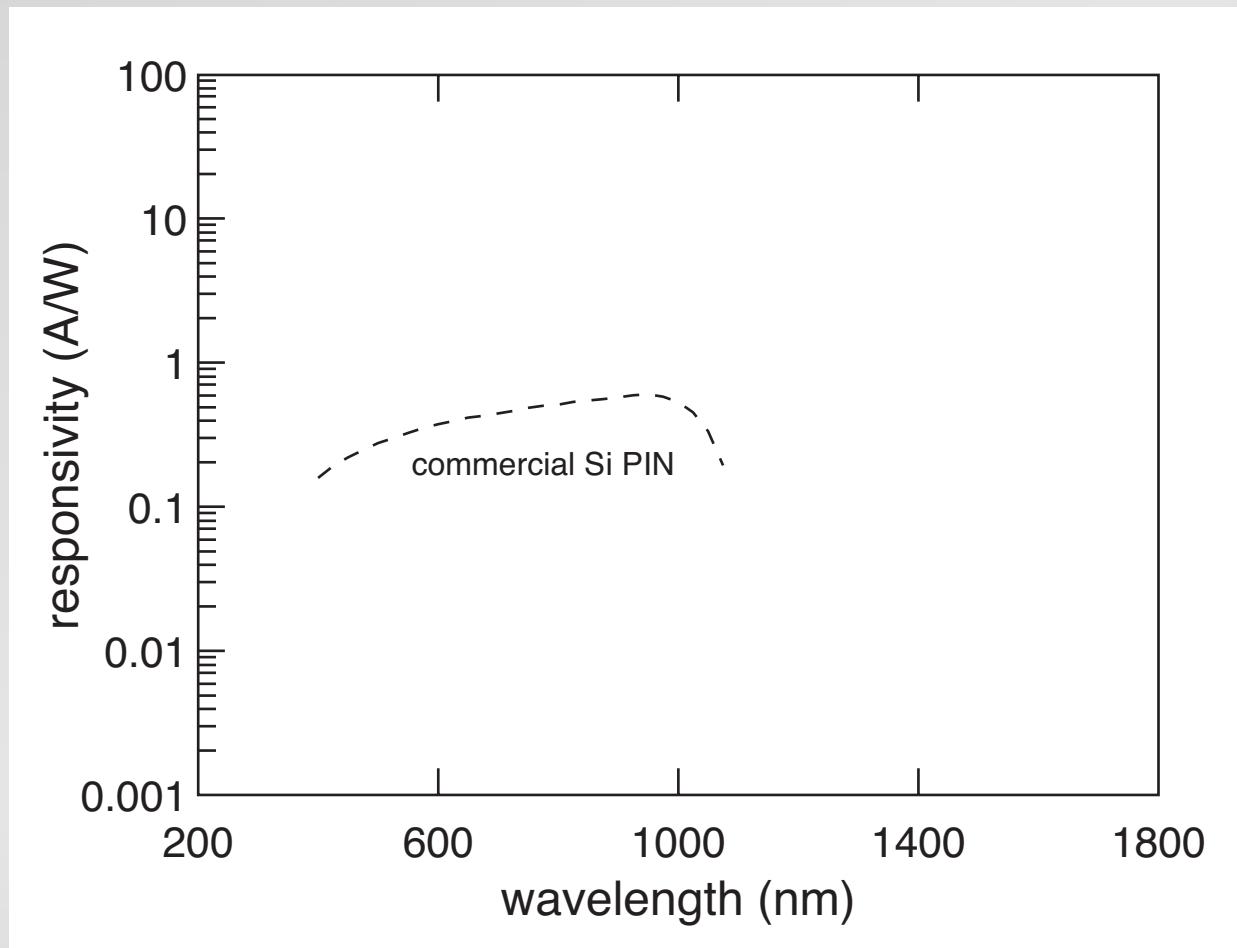
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I/V characteristics



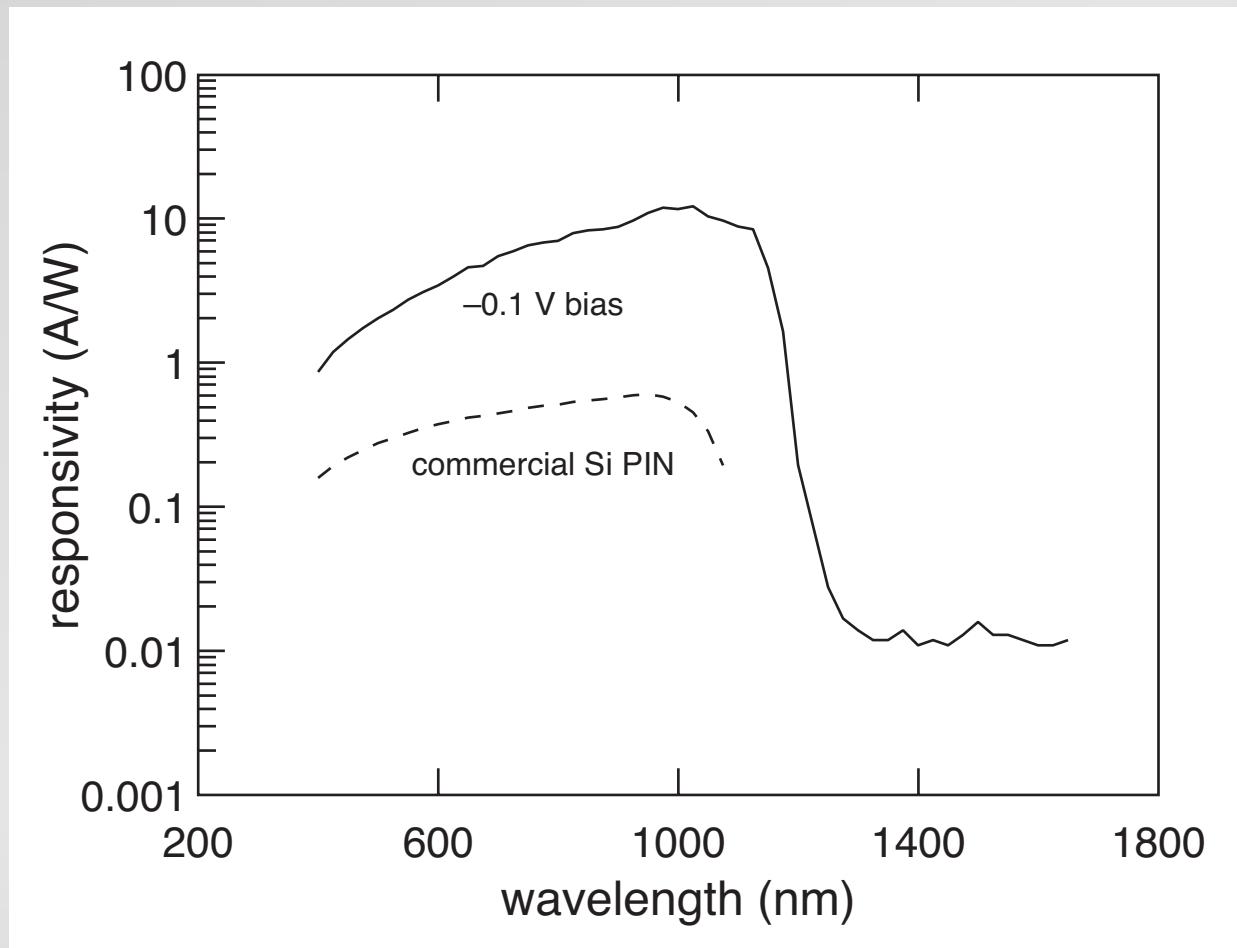
Detectors

responsivity



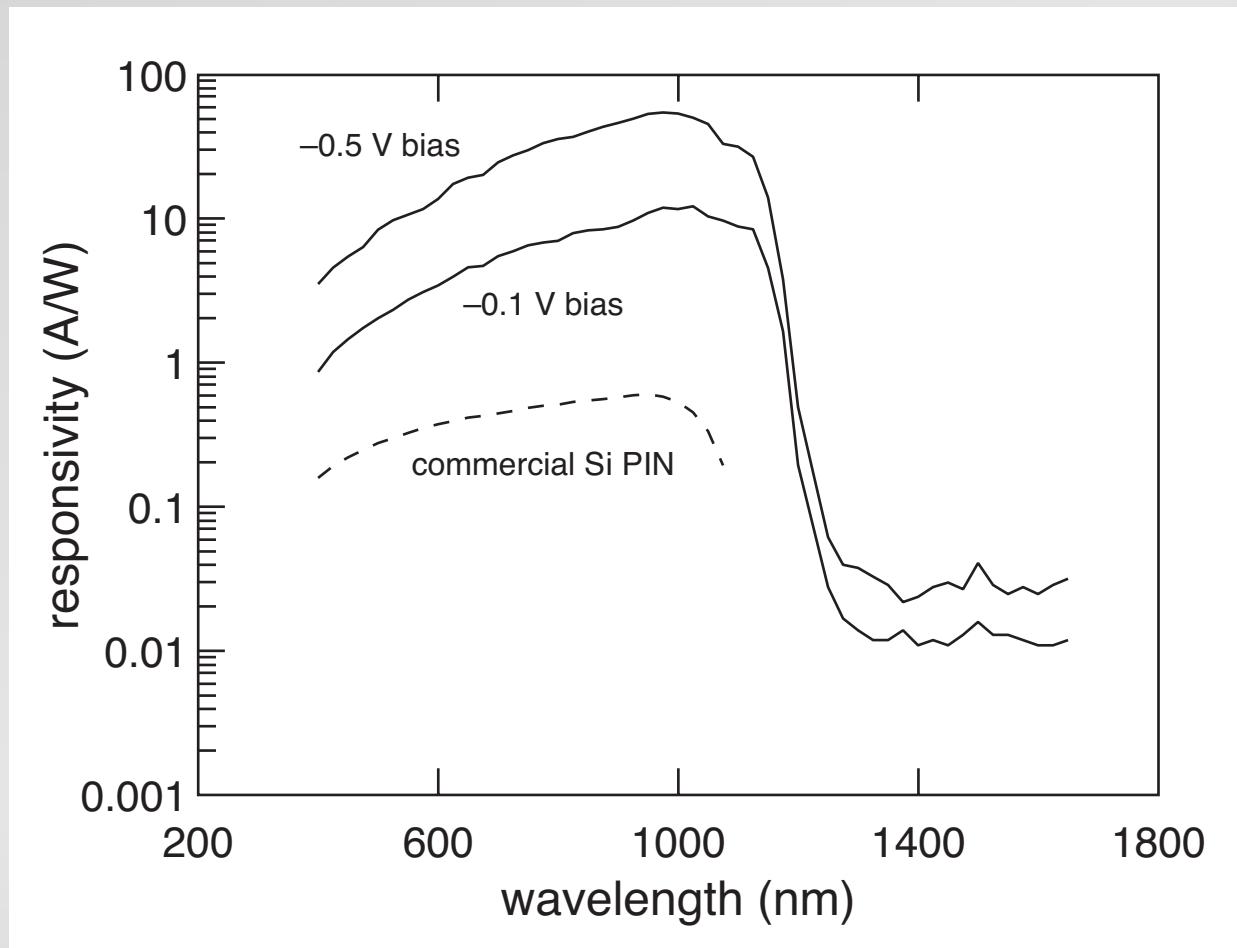
Detectors

responsivity



Detectors

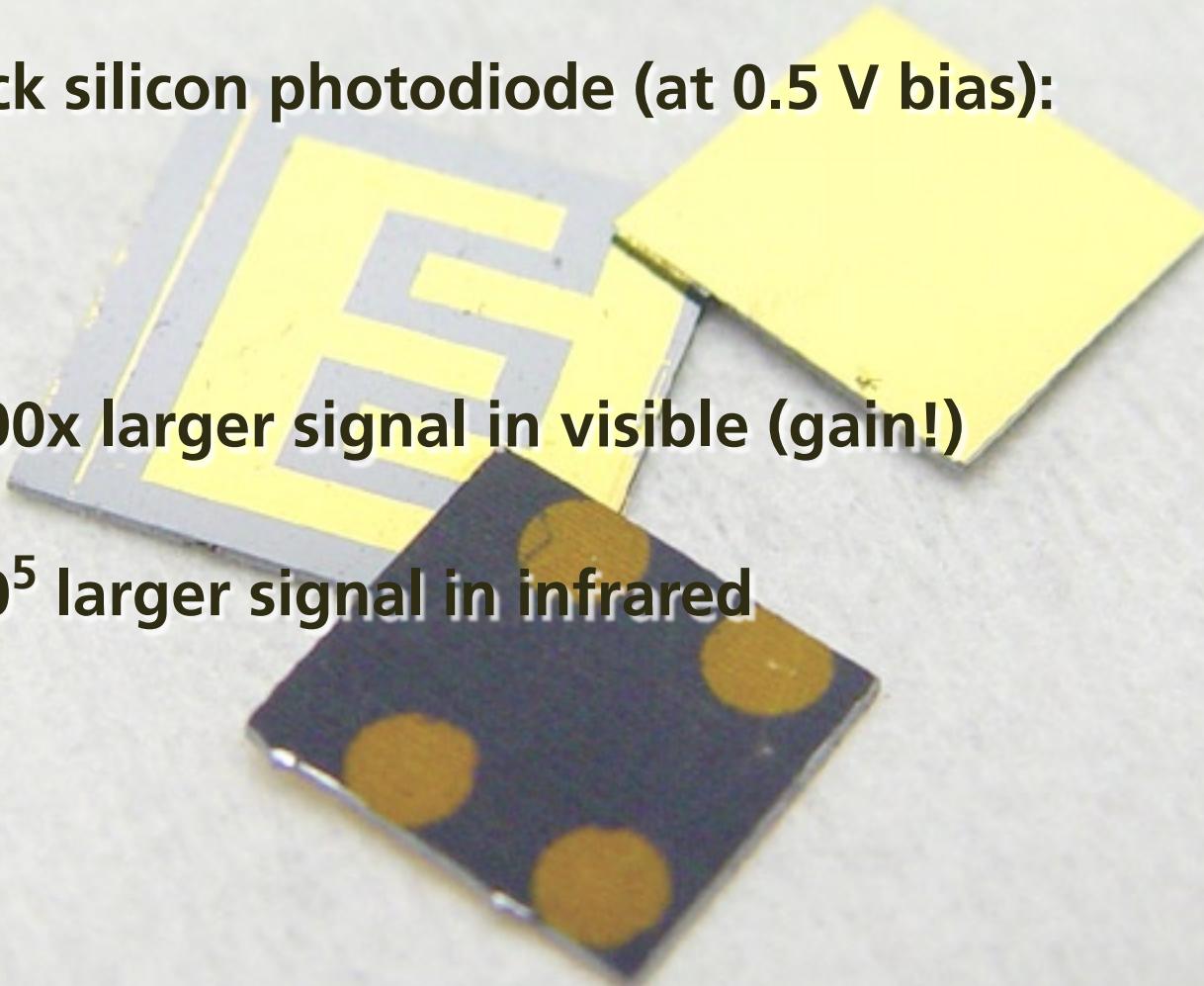
responsivity



Detectors

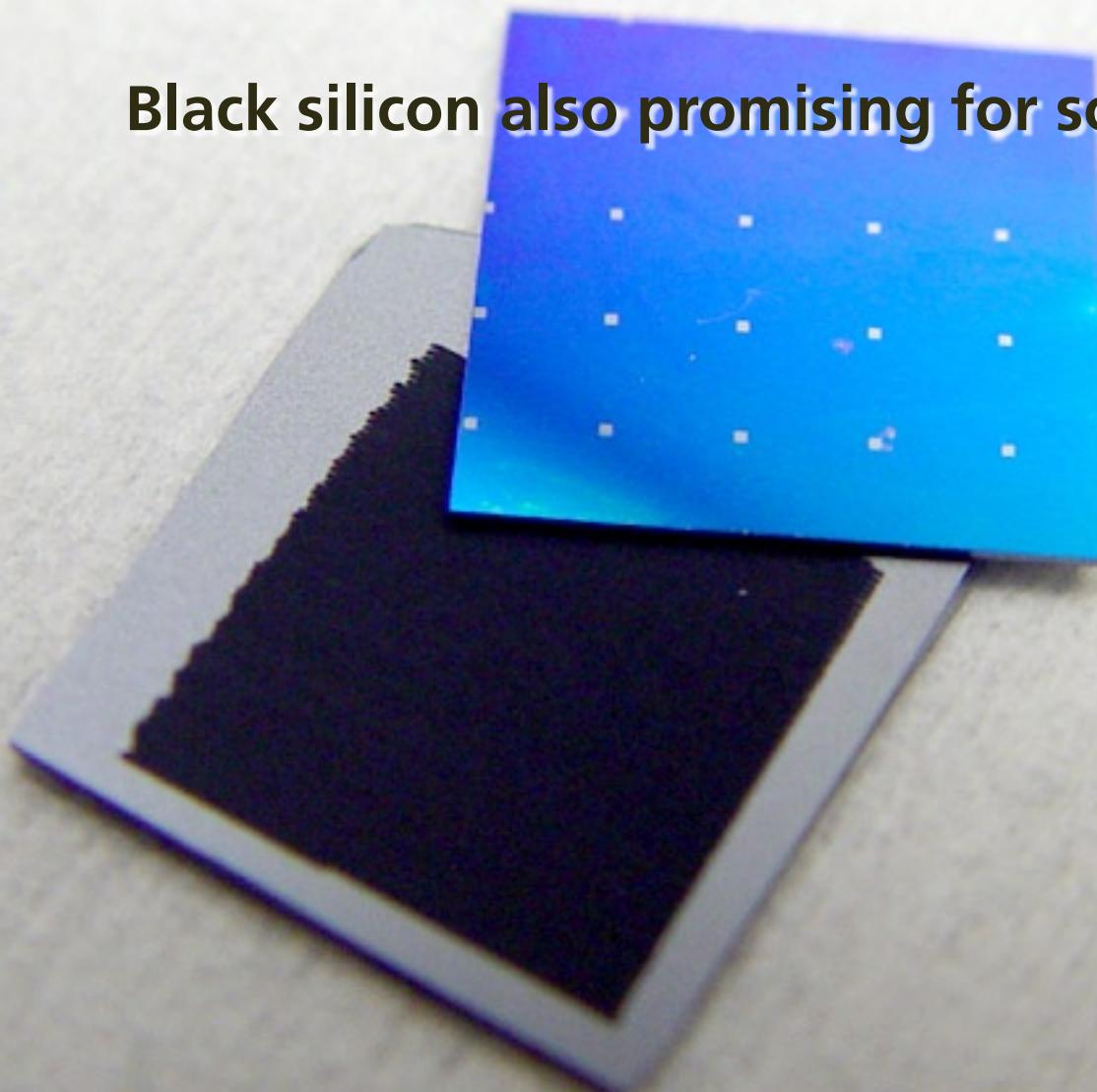
Black silicon photodiode (at 0.5 V bias):

- 100x larger signal in visible (gain!)
- 10^5 larger signal in infrared



Detectors

Black silicon also promising for solar cells



Outline

- properties
- structural and chemical analysis
- detectors
- outlook

Outlook

A forest of silicon spikes could revolutionise solar cells and give you painless injections. **Bruce Schechter** peers into the mysterious world of black silicon

TALL, DARK AND STRANGER

WE ALL love stories of serendipity. They seem to hark back to a time when a fogged photographic plate or a filthy Petri dish could change the world. Even today, when financial constraints keep the role of chance to a minimum, science is still sometimes a spontaneous act, a freelance exploration of the unknown. It often starts in front of a blackboard when one scientist says, "I wonder what would happen if . . ." and the other one replies, "Let's give it a try."

The result of one such conversation two years ago in Eric Mazur's laboratory at Harvard University is a new form of silicon as soot. What started life as

semiconductors with a powerful laser. In the early 1990s, Mazur's was the first academic lab in the world to get its hands on a femtosecond laser. This device produces pulses of light that are hundreds of billions of times brighter than the Sun. Its immense power is delivered extremely quickly: each pulse lasts a mere fraction of a trillionth of a second.

These flashes of laser light have provided researchers with a new way to probe the characteristics of many materials (*New Scientist*, 19 February 2000, p 34). Mazur's group was using the powerful femtosecond pulses to study the surface chemistry of metals. But Her, who is now at the Lawrence Livermore Laboratory in California, had been wondering for years what

he

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silicon

oxide,

black," he says. So what was goi

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With no clearer idea than this, the researchers began firing 100-femtosecond pulses of laser light through the windows of their chamber, through the SF₆ gas onto the shiny silicon wafer. After firing about 100 pulses they cracked the wafer, the chamber and removed the wafer. He saw a tiny black spot at the focal point of the laser beam. A burn, perhaps. That Mazur knew that silicon doesn't melt, he says. So what was going on?

Outlook

• detector technology

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TALL, DARK AND STRANGER

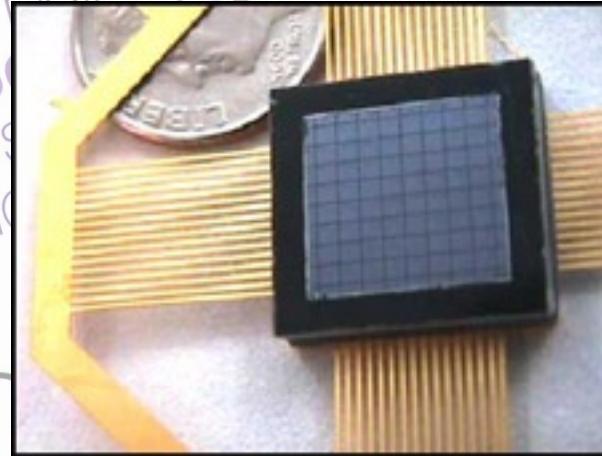
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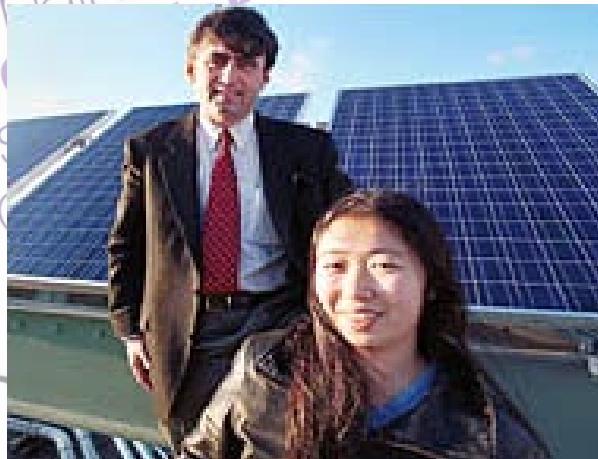
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Outlook

- detector technology

- solar cells

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- solar cells
- display technology

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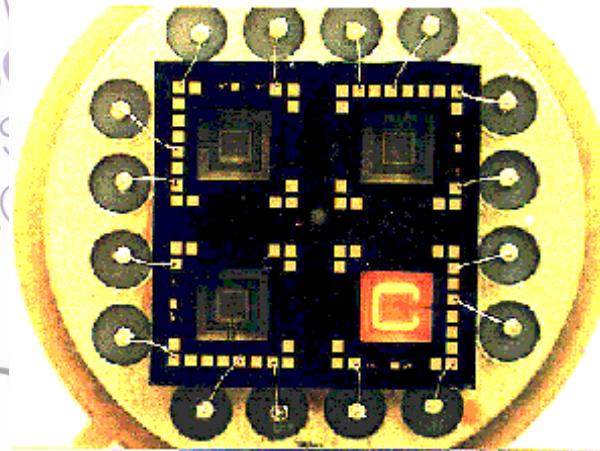


Outlook

- detector technology
- solar cells
- display technology
- biosensing

New Scientist 13, 34 (2001)

A forest of silicon spikes could revolutionise solar cells and give you painless injections. Bruce Stansfield peers into the mysterious world of black silicon.



TALL, DARK AND STRANGER

WE ALL love stories of serendipity. They seem to hark back to a time when a fogged photographic plate or a filthy Petri dish could change the world. Even today, when financial constraints keep the role of chance to a minimum, science is still sometimes a spontaneous act, a freelance exploration of the unknown. It often starts in front of a blackboard when one scientist says, "I wonder what would happen if . . .", and the other one replies, "Let's give it a try."

The result of one such conversation two years ago in Eric Mazur's laboratory at Harvard University is a new form of silicon soot. What started life as

semiconductors with a powerful laser. In the early 1990s, Mazur's was the first academic lab in the world to get its hands on a femtosecond laser. This device produces pulses of light that are hundreds of billions of times brighter than the Sun. Its immense power is delivered extremely quickly: each pulse lasts a mere fraction of a trillionth of a second.

These flashes of laser light have provided researchers with a new way to probe the characteristics of many materials (New Scientist, 19 February 2000, p 34). Mazur's group was using the powerful femtosecond pulses to study the surface chemistry of metals. But Her, who is now at the Lawrence Livermore Laboratory in California, had been wondering for years what

he could do to semiconductors like

around the laboratory," he claims. Well, it was almost the only reason. A short laser pulse will break down SF₆ into sulphur and fluorine radicals, which will attack a silicon substrate. Hydrogen fluoride is used to etch silicon. So we thought maybe the SF₆ would decompose and then the fluorine would somehow react with the silicon," Mazur explains.

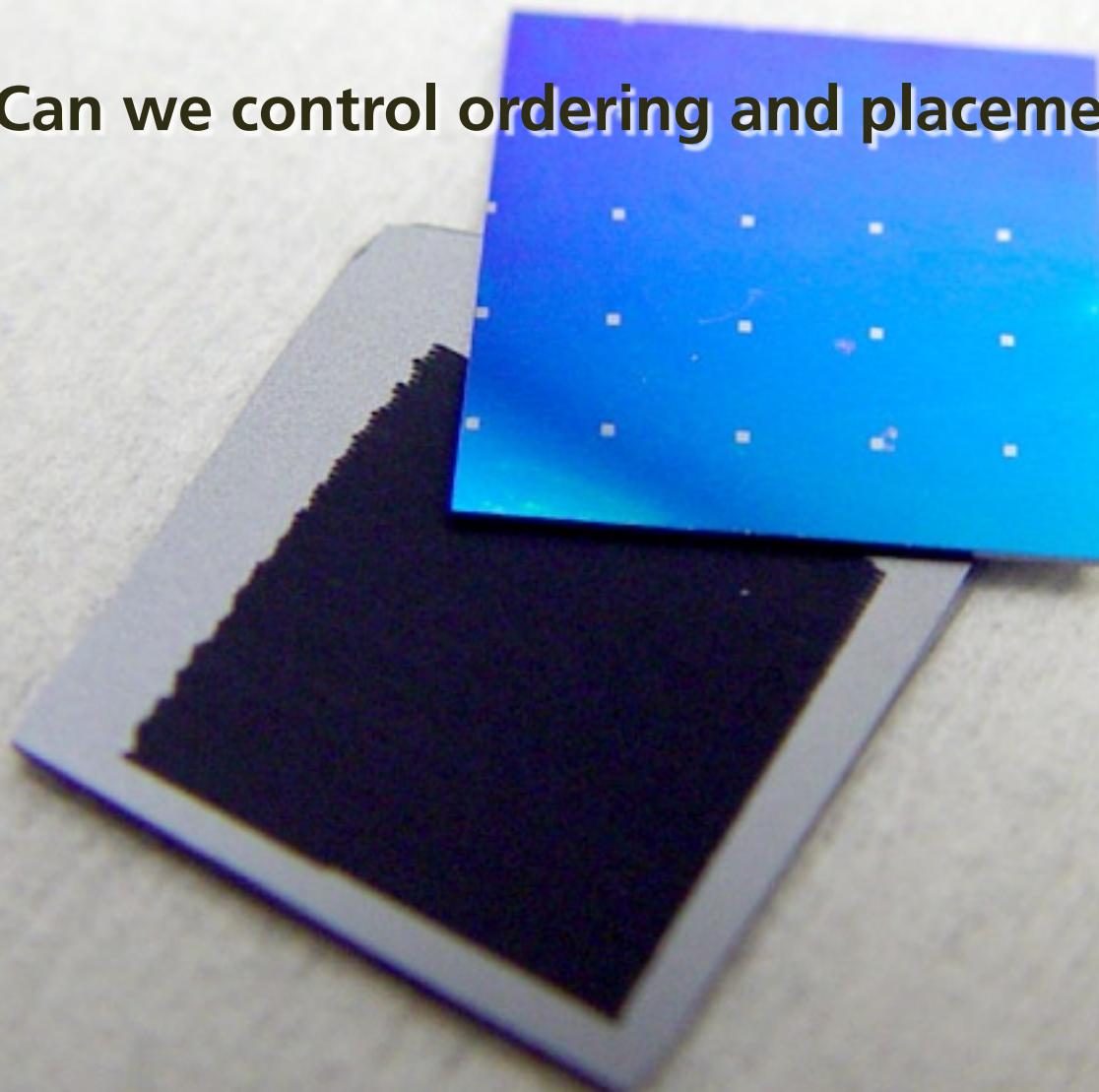
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"You can get silicon oxide, but it's

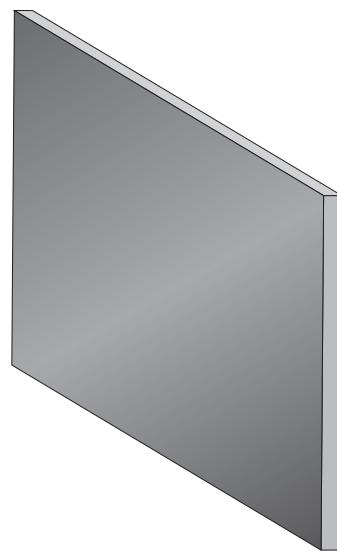
black," he says. So what was going on?

Detectors

Can we control ordering and placement of spikes?



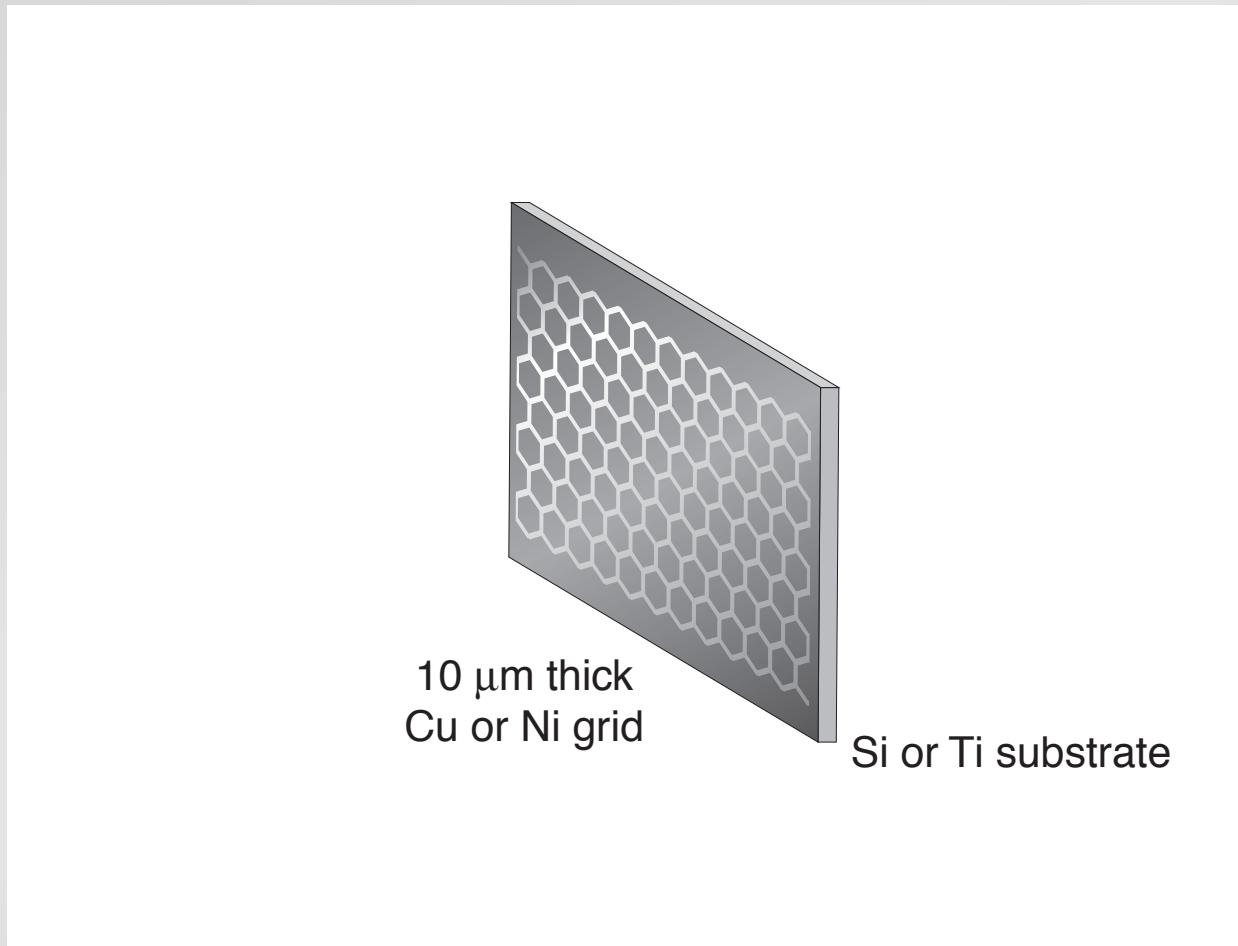
Outlook



Si or Ti substrate

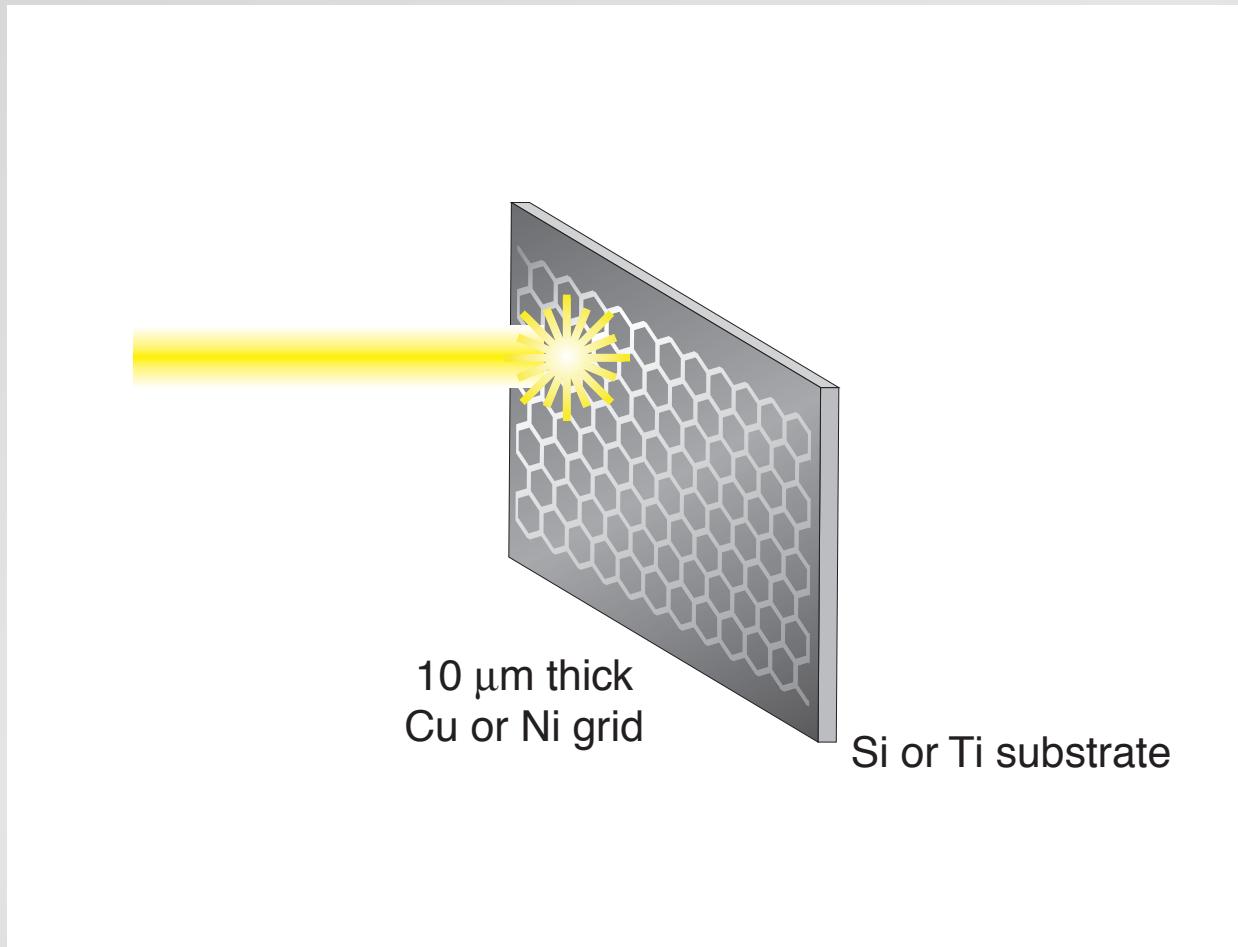
Outlook

place grid in front of sample



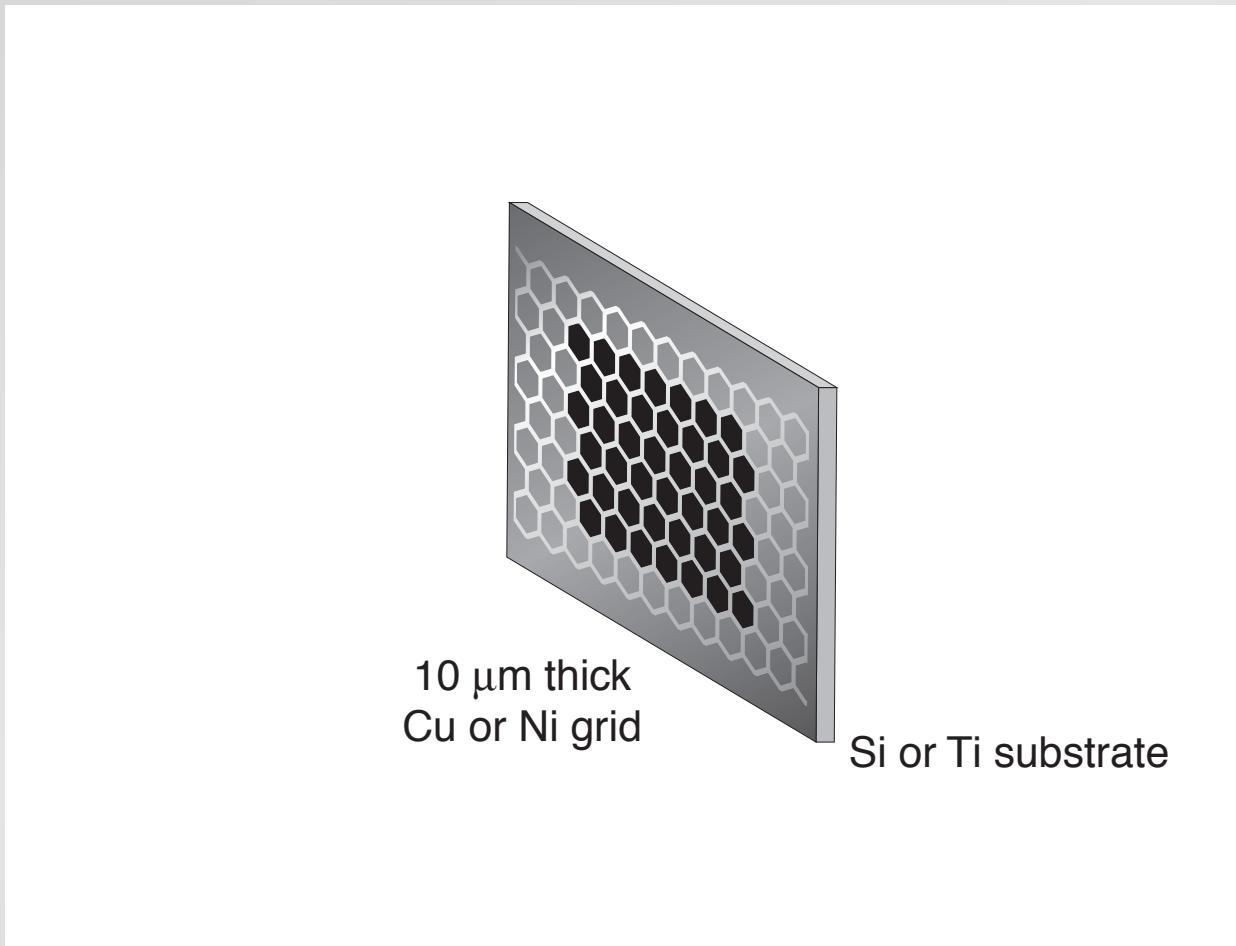
Outlook

scan laser beam



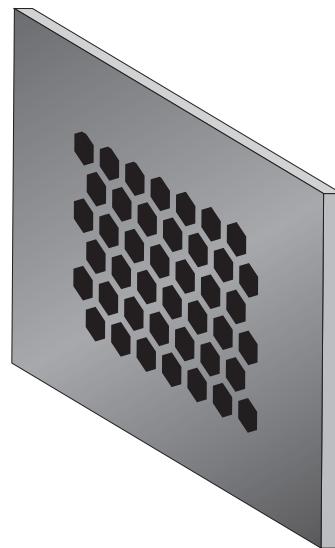
Outlook

scan laser beam

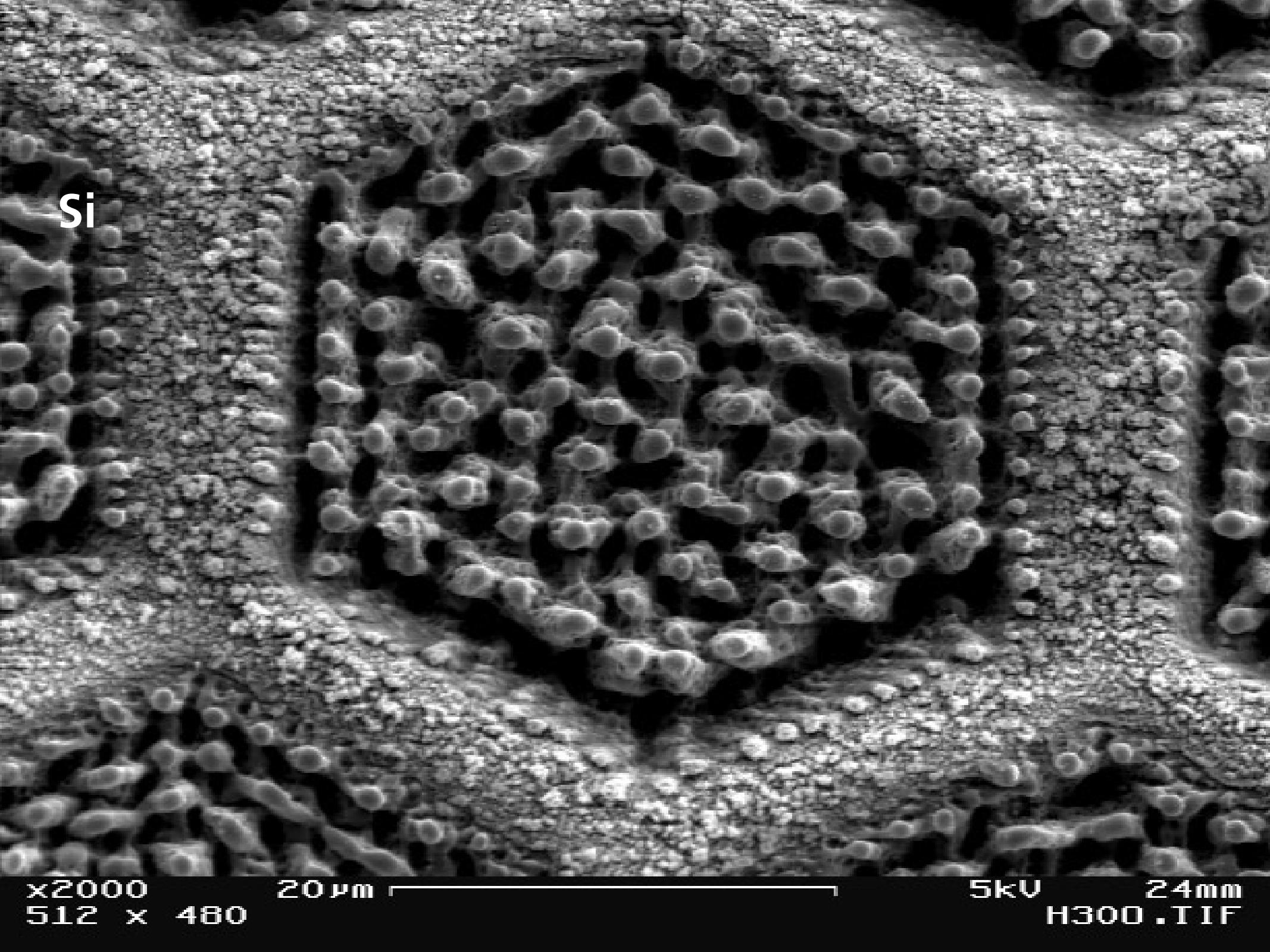


Outlook

remove grid



Si or Ti substrate



Si

x2000

512 x 480

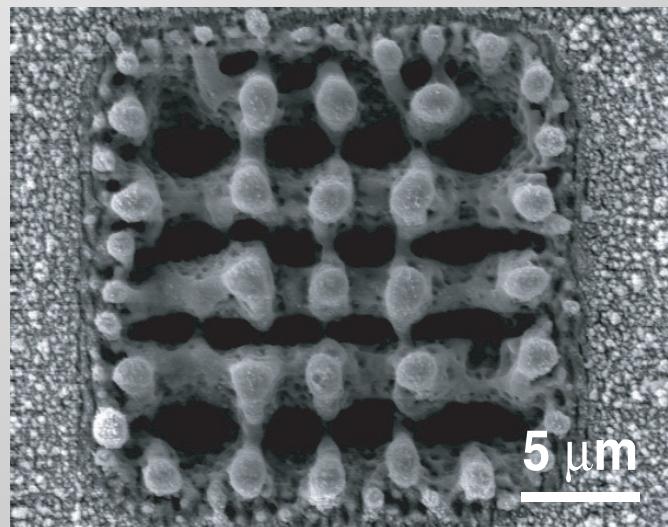
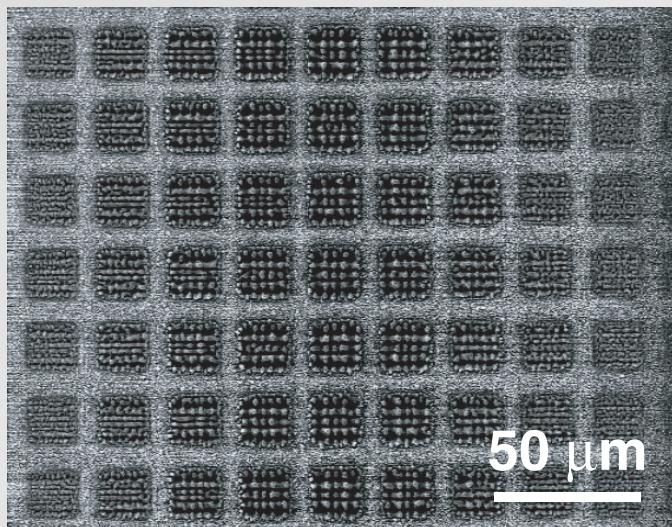
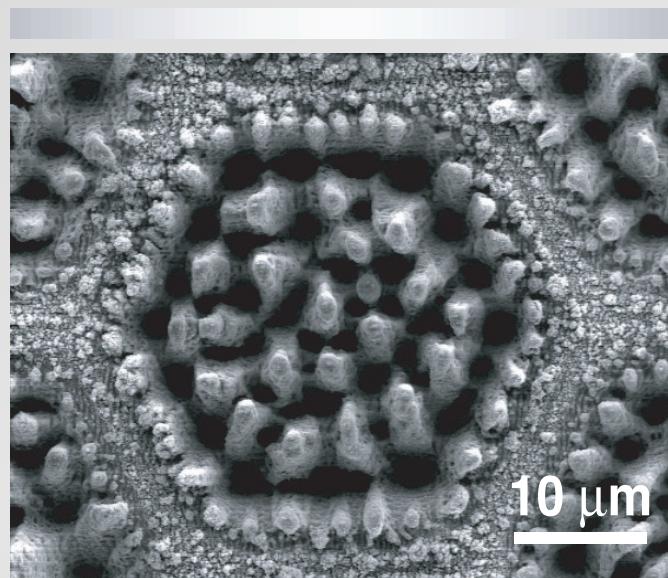
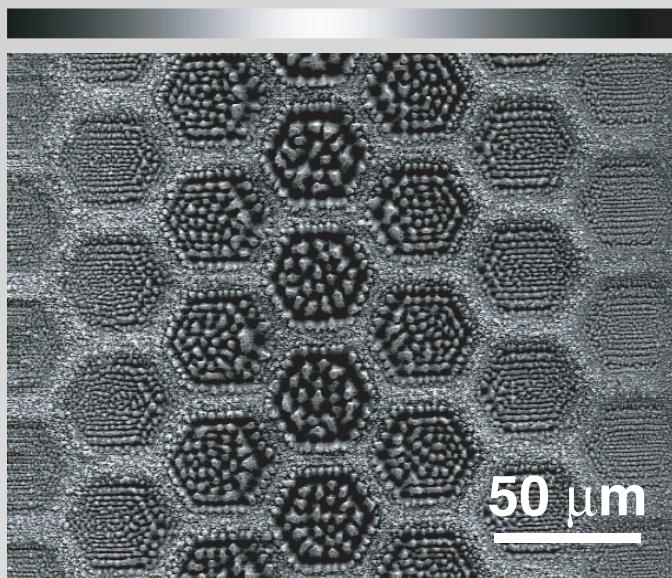
20 μ m

5kV

24mm

H300.TIF

Outlook



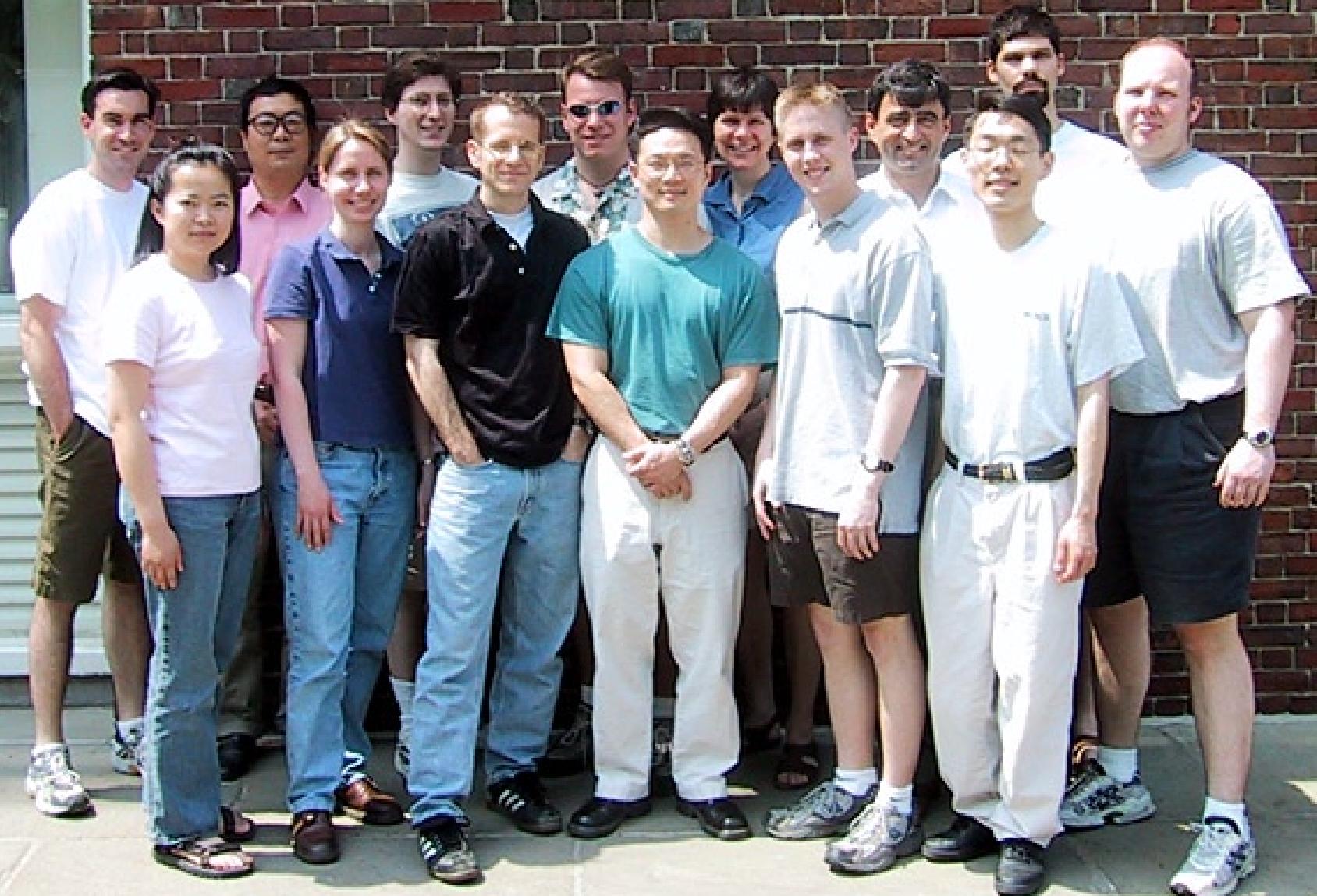
Summary



Summary

- near unity absorption from near-UV to near-IR
- maskless process, easily integrated with microelectronics
- grid improves positioning and spacing
- many promising applications

CORDON MCKAY
LABORATORY OF
APPLIED SCIENCE



A photograph of a group of approximately 15 people, mostly men, standing in two rows in front of a red brick building. The building has a large, faint inscription in the bricks that reads "CORPORATION FOR SCIENCE AND TECHNOLOGY".

Funding:

Army Research Office

DARPA

Department of Energy

NDSEG

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